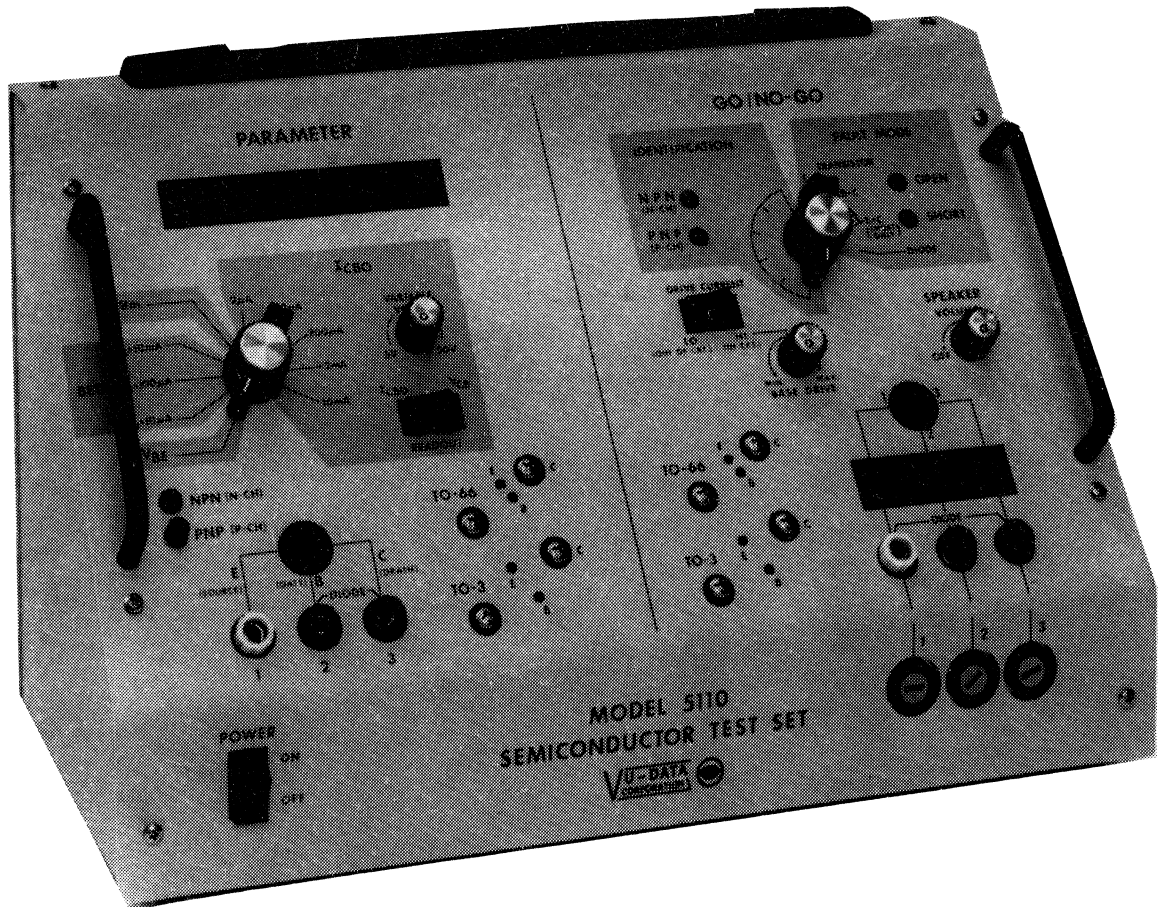


OPERATION
APPLICATION
MAINTENANCE



MODEL 5110 SEMICONDUCTOR TEST SET

WARRANTY AND ASSISTANCE

WARRANTY

VU-DATA warrants to the original Buyer of goods of VU-DATA design and manufacture for a period of one (1) year from the date of shipment from VU-DATA that the goods under the order will be of merchantable quality free from defects in material, workmanship and design each as determined at the date of shipment by VU-DATA. VU-DATA will not be liable for any design or design modification requested by or furnished by Buyer and incorporated into the goods.

Satisfaction of this warranty will be limited to replacement or repair or modification of, or issuance of credit for the goods involved at VU-DATA'S option. Repair or modification of the goods must be performed at VU-DATA or at any repair center authorized by VU-DATA to make such repairs or modifications as may be necessary. Buyer shall be responsible for transportation to the point of repair and for return shipment to Buyer. Such warranty satisfaction is available only if Buyer promptly notifies VU-DATA in writing upon discovery of the alleged defect and obtains from VU-DATA authorization for the return of the goods and VU-DATA'S examination of subject goods discloses that any defect is not the result of misuse; neglect; improper installation; improper operation; improper maintenance or repair; accident; or unusual deterioration or degradation due to electrical or electromagnetic environment. Should VU-DATA'S examination of subject goods determine that no defect exists, Buyer shall be assessed an inspection and calibration fee.

THE WARRANTY DESCRIBED HEREIN SHALL BE IN LIEU OF ANY OTHER WARRANTY, EXPRESSED OR IMPLIED, INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF MERCHANTABILITY OR FITNESS FOR A PARTICULAR PURPOSE.



ASSISTANCE

Certain limited procedures listed in the Maintenance Chapter of this manual, may be performed by competent, customer personnel with the expressed permission of VU-DATA Corporation. Beyond these limited procedures the opening, alteration or repair of this equipment except by VU-DATA personnel or VU-DATA authorized repair facilities will void the warranty. VU-DATA is not liable for incidental or consequential damage. See Warranty on inside front cover. If any question or confusion arises concerning the warranty, check with VU-DATA before taking any action.

CALL (619) 452-7670

When information, assistance or authorization is required refer to the serial number on the back of the unit when contacting VU-DATA.

MODEL 5110

Serial Number _____

TECHNICAL MANUAL

OPERATION APPLICATION MAINTENANCE

PREFACE

This manual contains the information required by personnel at all levels of involvement to understand the functions, internal operation, application, and maintenance requirements of the Vu-Data Model 5110 Semiconductor Test Set.

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WARNING

Before removing the covers for trouble shooting, read and observe the trouble shooting precautions on page 29. Circuits are exposed which could become hazardous if not handled properly.

CAUTION

ALWAYS remove the AC power cord from the connector on the rear panel before removing back and/or bottom covers. The interior of this instrument contains voltage levels which could be hazardous to your health. AC power lines exposed when covers are removed.

CAUTION

NEVER apply power to device or P.C. board being tested while connected to the Model 5110. All STS testing of in-circuit components MUST be performed with no circuit power applied.

CAUTION

Avoid the use of chemical cleaning agents such as MEK, laquer thinner, or strong acids or alkali. These solvents will cause paint removal, deterioration of switches and melting of plastic parts.

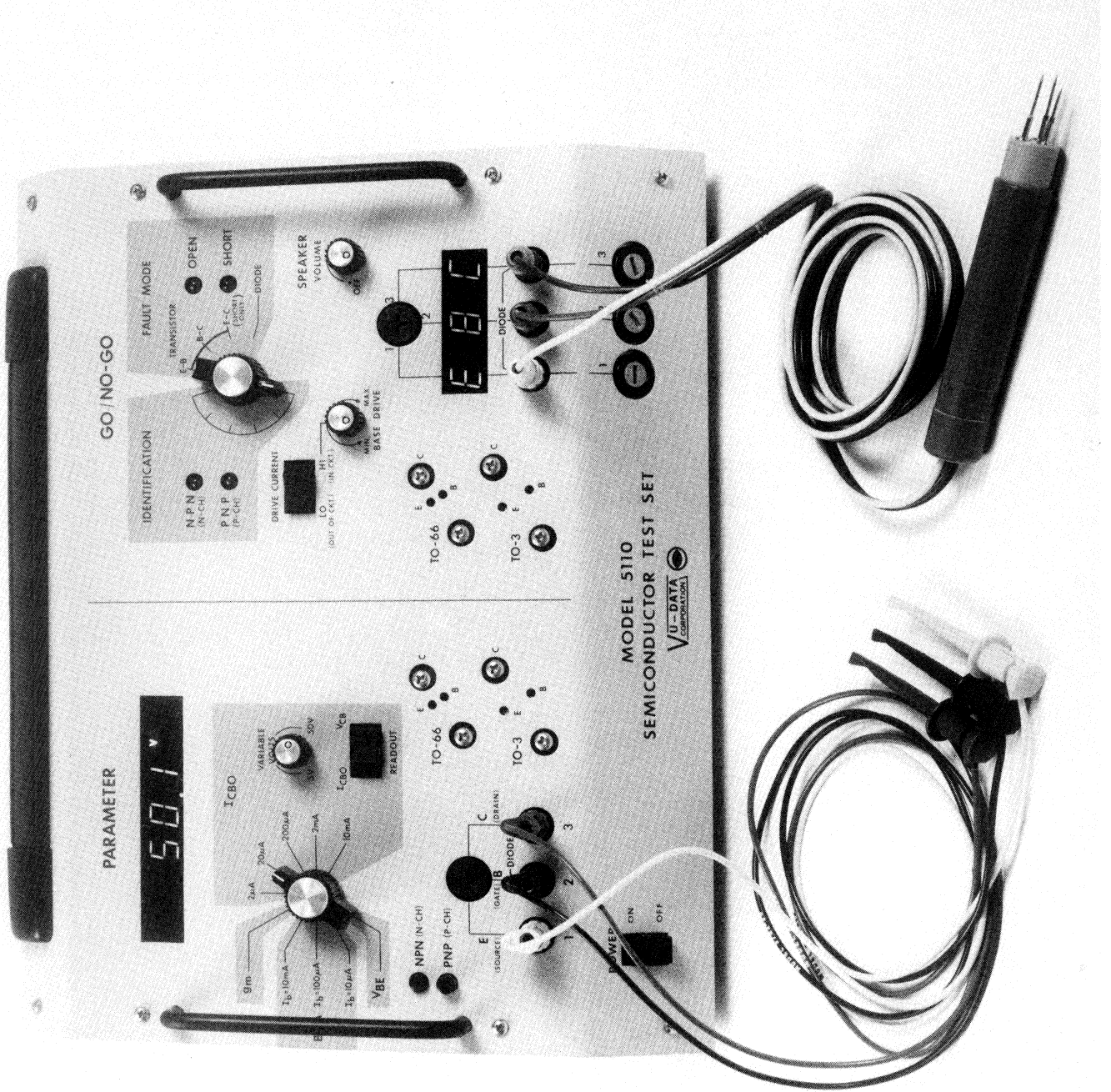


Figure 1. Model 5110 Semiconductor Test Set

This manual provides information relative to the use of the Model 5110 SEMICONDUCTOR TEST SET (STS) manufactured by VuData Corporation, 7122 Convoy Court, San Diego, California 92111. The Model 5110 is shown in Figure 1.

This manual contains complete operation, application, calibration, troubleshooting, and maintenance information required by the user or service technicians in the operation or servicing of the Model 5110 and is presented as follows:

- Introduction
- Preparation For Use
- Theory of Operation
- Operating Instructions
- Applications
- Troubleshooting
- Calibration
- Maintenance and Service
- Parts Listing
- Drawings

General Description

The Model 5110 STS is a portable “general purpose” type of instrument used as an in-circuit or out-of-circuit semiconductor tester. The Model 5110 is a single unit suitable for bench-top use. Four rubber feet are provided on the bottom of the unit. A front panel is angled for improved visibility and ease of operation. All controls for the STS are front panel mounted for operator convenience.

The Model 5110, provides a simple, sure and inexpensive way to detect defective semiconductors in-circuit or out-of-circuit, without the need of circuit power. The STS provides all the circuitry required for even the most inexperienced user to effectively determine “Good” or “Bad” components, while providing a high level of sophisticated testing for the experienced technician or engineer where required.

The test set has plug-in sockets for TO-3, TO-5 and TO-66 type semiconductors. Three fused jacks are provided for testing of other types of

semiconductors and diodes for in-circuit-testing of semiconductors using mini-grabbers or the three-prong test probe.

The 5110 uses a high-current, low duty cycle pulse technique to test transistors. An electronic switching circuit is used to enable the user to identify the terminals of the device-under-test (D.U.T.) in most in-circuit tests and all out-of-circuit tests.

Circuitry is provided for out-of circuit measurement of transistor beta and FET g_m , and the testing of high current devices at rated current (up to 2 amperes) without over-dissipation and leakage.

The instrument is designed for ease of operation, with a minimum of control functions, allowing faster and easier testing of large quantities of parts.

Package Size

The Model 5110 is a compact 8.5 inches high by 12.5 inches wide by 6.5 inches in depth. The instrument case is of aluminum. A power plug and fuse holder are located on the rear panel.

Features

- A 10-position Identification/Fault Mode switch sequentially connects the device-under-test in all possible configurations making it unnecessary to know the device terminal identification. Lead identification is displayed on 3-Seven segment displays. (i.e., E-B-C).
- HI-LO Switch for Drive Currents.
- Automatic polarity indication of NPN or PNP devices and N-channel or P-channel FET's.
- Adjustable Audible Tone tells when the DUT is good—no need for visual check of instrument. Volume control allows for varying of signal to working conditions.
- Measures beta of low-power and high-power transistors in 3 ranges.
- Measures g_m in 1 range.
- Measures I_{CBO} in 5 ranges.
- Automatic current limiting of DUT.

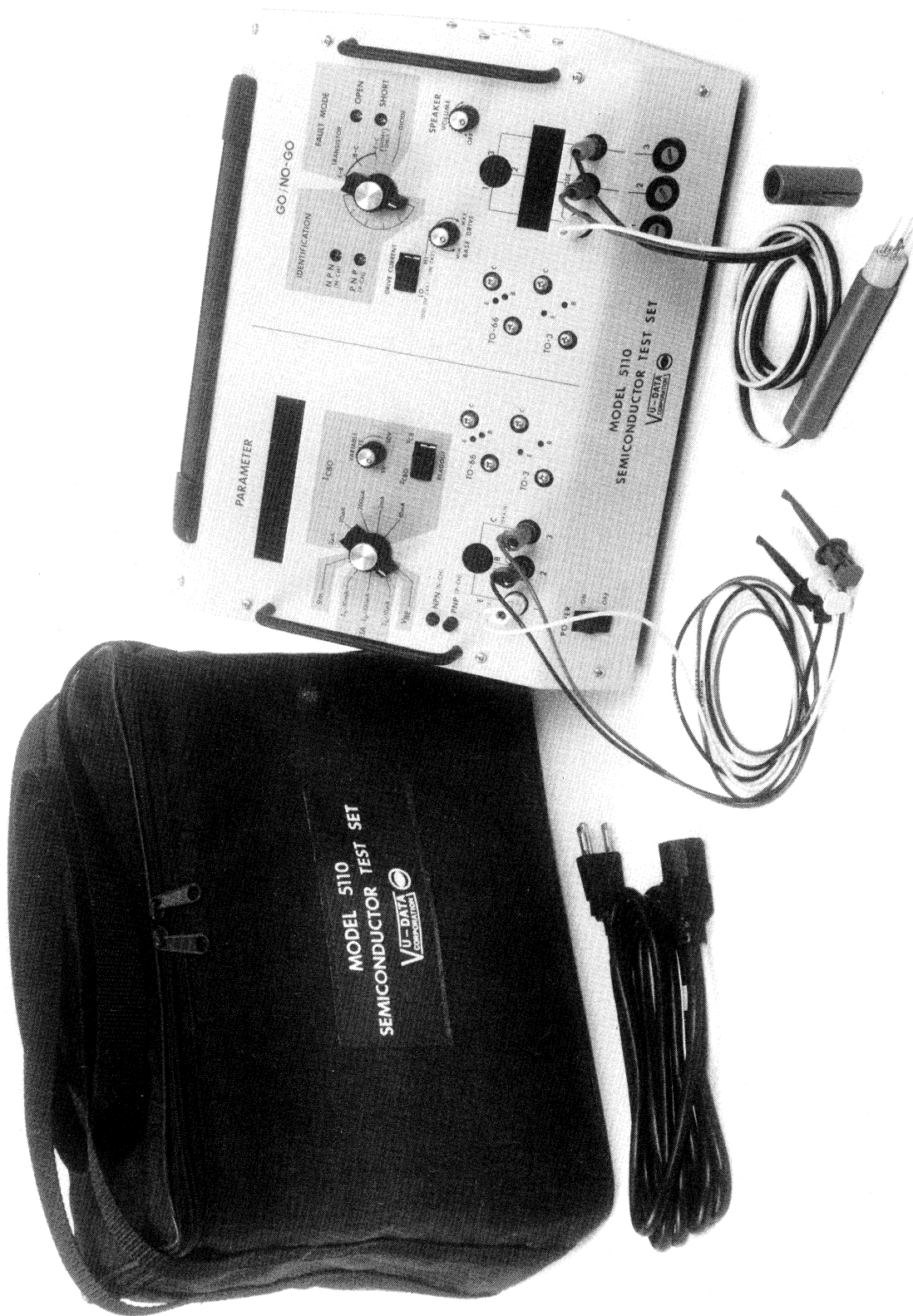


Figure 2. Model 5110 and Accessories

- Digital Read-out of current, voltage, beta and g_m .
- Identifies device as silicon or germanium.
- Switch for current/voltage comparison of collector/base (I_{CBO} and V_{CB}).
- Choice of test leads or 3 separate types of front panel sockets for out-of-circuit tests.
- Fused test leads for positive connection to devices in different locations. Go/No-Go section only.

Capabilities of the Model 5110

- Determines GOOD or BAD transistors or FET's in- or out-of-circuits.
- Determines GOOD or BAD diodes in- or out-of-circuit.
- Identifies fault of bad device (Open, Short)
- Identifies leads of transistors and displays findings as E-B-C on seven segment displays.
- Identifies gate lead of FET.
- Indicates polarity of good devices (NPN or PNP; N or P channel FET's).
- Identifies Cathode-Gate-Anode leads of SCR's.
- Identifies Cathode of Diodes.
- Measures breakdown and leakage parameters of transistors.
- Tests all types except triacs, diacs and diode arrays.

Items Furnished

The Model 5110 comes complete with the following items:

- a) One 6-foot 3-wire Power Cord PN-2-70009
- b) One Technical Manual PN-4-20413
- c) One TEST LEAD SET containing: 3 mini-grabbers PN-4-20415
- d) One Probe PN-4-20414
- e) One carrying case P/N51102020

Associated Equipment

To further enhance the component testing level, Vu-Data also provides the Model 3110 In-Circuit Component Tester and the Model 3120 IC Test Fixture. The Model 3110 is a portable "special purpose" type of oscilloscope and signal processing instrument that is used as an in-circuit component tester providing a simple and inexpensive way to detect defective components in-circuit or out-of-circuit, without the need of circuit power. When users of the Model 3110 asked for an even easier way to test integrated circuits (IC's), the Model 3210 was designed to meet this need. Although the Model 3210 was designed to operate with the Model 3110 for good-bad-no-power comparison tests, its versatility also allows it to be used with a dual trace oscilloscope like Vu-Data's Model 975 or a DVM to compare waveforms or voltages on any pin of an IC (from 1-40) in an operating circuit. Tests of IC's having 8 to 40 pins are accomplished WITHOUT having to reverse the IC.

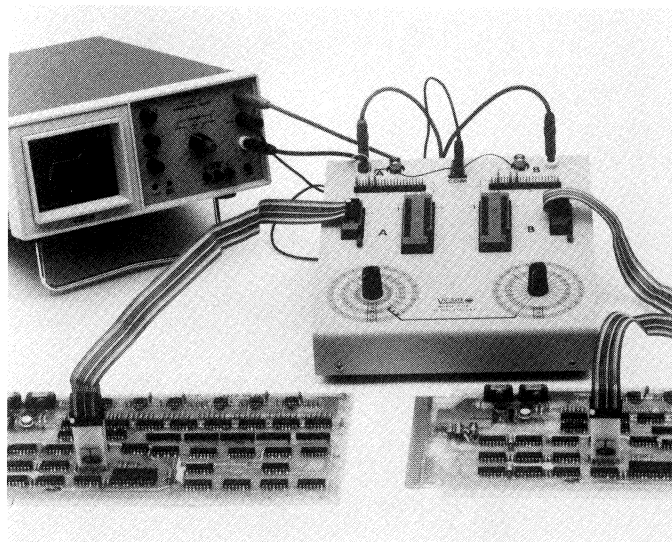


Figure 3. Model 3110 and Model 3210

GENERAL. The Model 5110 is a solid state semiconductor analyzer capable of both in-or out-of-circuit GO/NO-GO testing and out-of-circuit Parameter testing.

CLASSIFICATION. The Model 5110 is Type III, Class 5, Style E, and Color R for Navy applications in accordance with MIL-T-28800 with the following exceptions:

- a. The relative humidity requirement is limited to 45% during leakage current measurements.
- b. The pulse shock testing requirement is not invoked.
- c. The EMI requirement is not invoked.
- d. The 400 Hz nominal power requirement is not invoked.

OPERATIONAL CHARACTERISTICS

LEVEL 1 AND 2. The Model 5110 is capable of testing semiconductors either out-of-circuit or in-circuit with circuit power removed. A selector switch for HI-LO drive currents is provided with the shunt limits listed below.

- a. **GO CONDITION (IDENTIFICATION MODE).**
A good device will be identified as to Good or Bad, type (NPN or PNP) and the Lead orientation indicated with an Alpha-numeric display.
- b. **NO-GO CONDITION (FAULT MODE).** A bad device will be indicated as OPEN or SHORT and the junction involved will be identified with an Alpha-numeric display.
- c. **DIODE TEST.** Indicates short, open or identifies the cathode for a good diode.
All GOOD/BAD, polarity and lead identification is implemented automatically with front panel indicators. No separate charts or manuals are required to interpret front panel indicators.

SHUNT LIMITS. The 5110 is capable of in-circuit testing of signal diodes and bipolar transistors subject to the following limits.

- a. **DIODES.** Diodes in a circuit that shunts the junction with a dynamic impedance of **100 ohms or more.**
- b. **TRANSISTORS.** Transistors in a circuit that presents a dynamic impedance of:
 - (1) Base to Emitter of **100 ohms or more.**
 - (2) Base to Collector of **100 ohms or more.**
 - (3) Collector to Emitter of **25 ohms or more.**

LEVEL 3 PARAMETER. The Model 5110 will perform the following out-of-circuit, dynamic parameter measurements:

- a. **BETA,** from 0 to 1,999 using 3 separate base drive currents. Base drive is a 2% duty cycle pulse 300 μ S wide.
- b. **Collector-To-Base Leakage Current, I_{CBO} ,** from less than 100 nA to 10 mA in 5 ranges with 10 nA resolution on the most sensitive range. Bias voltage is continuously variable from 5 volts to 50 volts.
- c. **Base-to-Emitter saturation voltage, $V_{BC(SAT)}$,** over a range of 0 to 1.999 volts full scale with a resolution of 0.005 volts or less.
- d. **FET Transconductance (G_m)** from 0 to 19.99 $m\Omega$ (milli-mhos).
- e. **SEMICONDUCTOR COMPOSITION.** The Model 5110 will identify the semiconductor material composition as either silicon or germanium with a front panel readout of "SI" or "GE".
- f. **BIAS CURRENT RANGES.** In the Beta Mode, peak base currents of 10 μ A, 100 μ A and 10 mA are provided.
- g. **ACCURACY.** The accuracy of all parameter measurements made by the Model 5110 is \pm (3% of reading + 10 digits) for any mode or range.

INDICATORS. The Model 5110 uses LED digital readouts and annunciators for parameter measurements, LED indicators for GO/NO-GO, polarity and fault indicators, and LED digital alpha-numeric identification of device leads in GO/NO-GO testing. A selectable audio indicator with variable volume is provided in GO/NO-GO testing.

EQUIPMENT PROTECTION. The Model 5110 input jacks used for in-circuit GO/NO-GO testing are capable of withstanding up to 600 Vpms without damage to internal circuits. Protection fuses for the 3 leads are mounted in standard front panel accessible fuse holders.

TEST SOCKETS. The 5110 is provided with front panel mounted test sockets for TO-5, TO-66 and TO-3 case configurations in addition to the input banana jacks. Separate sockets are provided for the GO/NO-GO and parameter test sections. The sockets provided are specially designed for test applications to provide a high number of insertions.

POWER. The Model 5110 is powered in accordance with the nominal power requirements of MIL-T-28800 except operation from 400 Hz source power is not provided. The maximum power required for operation shall not exceed 20 watts.

PROTECTIVE CASE. A carrying case is provided to store all components of the test set and to protect them against the normal shock, vibration, and other environmental conditions encountered during use in more than one location. This protection shall be in accordance with the environmental requirements of Class 5 of MIL-T-28800.

ACCESSORIES. The following accessories are provided with each Model 5110.

- a. One 3-prong test probe with a 5-foot cable.
- b. One set of semiconductor sockets.
- c. One spares kit of replacement fuses.
- d. Three color coded "mini-grabber" test leads.
- e. A complete operator/maintenance manual with description, operating instructions, calibration procedures, schematic, and parts information.

CALIBRATION INTERVAL. After calibration, the Model 5110 will maintain the specified tolerance for a period of at least 1 year.

RELIABILITY. When invoked, reliability verification testing for the Model 5110 will comply with Type III, Class 5 environmental conditions of MIL-T-28800. MTBF is more than 2000 hours.

ELAPSED TIME INDICATOR. The Model 5110 is provided with an internally mounted, replaceable, minaturized, solid-state elapsed time indicator (ETI) capable of measuring and directly indicating the actual time that the equipment is in an operating condition. With the exception of mounting configurations, the ETI shall meet or exceed all requirements invoked by MIL-I-81219 for nonmercuriac indicating cells. The time range full-scale reading shall be 5000 hours.

DIMENSIONS AND WEIGHT. The size and weight of the Model 5110 is consistent with commercial capabilities and does not exceed the maximum dimensions for shipboard applications. Instrument dimensions are 12.5" wide by 8.5" high by 6.5" deep. Weight is less than 7 pounds. The carrying case is 14" wide by 9.5" high by 8" deep. Weight of carrying case and accessories is less than 2 pounds.

Acceptance of Delivery

Prior to accepting delivery, a careful inspection of the shipping container must be made. A severe gouge, abrasion or scratch; a badly battered corner or edge constitutes evidence of mishandling that may have damaged the unit. If there is any damage to the shipping container, a note of such must be signed by the carrier's representative acknowledging the damage before delivery can be accepted.

NOTE

In preparing to unpack the unit, provisions should be made to retain the shipping container and packing material for use in the event that it should become necessary to repack the unit for shipment to another installation or to return it to the factory.

A visual inspection for damage should be accomplished upon removing the instrument from the shipping container. If damage is not apparent until the instrument is unpacked, a claim for concealed damage should be placed with the carrier within 15 days of receipt. All shipping containers and filler materials must be kept for inspection.

Receiving Inspection

Whether or not any damage to the shipping container was noted, a thorough inspection of the unit is essential prior to application of power. Visually examine the:

- Cover for dents or abrasions
- Carrying case for damage
- Control panel for broken knobs or damaged switches
- Rear panel for damage to fuse holder or connector
- Lower front panel for broken knob, switches or fuse holders

If any scratches, abrasions, dents, bulges, cracks or other evidence of damage is noted, notify Vu-Data Corporation, Customer Service Department immediately. Call (169) 279-6572.

NOTE

To avoid cancellation of the warranty, do not apply power to a unit that has been dropped or damaged. Notify Vu-Data, requesting information as to disposition of damaged unit.

Reshipment

When reshipment of a Model 5110 becomes necessary, it should be packed in the original container in accordance with the following procedure:

1. Remove power cord and test leads.
2. Place cords in protective pocket of carrying case.
3. Place unit/carrying case in plastic bag.
4. Place unit in container.
5. Place lid on container.

Power Requirements

The Model 5110 input power requirements are 115 Vac, $\pm 10\%$, 50-60 Hz, 20 Watts maximum

First Time Operation

1. Connect the power cord to the connector on the rear panel.
2. Connect plug to 3-prong grounded AC receptacle.
3. Depress POWER rocker switch on lower front panel.
4. Observe indicators are illuminated.

Allow instrument to warm up for approximately two minutes before using. For use, follow operating instructions provide in this manual.

Function Checkout Procedures

The Model 5110 Semiconductor Test Set was aligned, calibrated and tested prior to shipment. The instrument is therefore ready for immediate use upon receipt. If the unit has passed receiving inspection, then the following function checkout tests may be performed.

NOTE

The Model 5110 is furnished with a detachable 3-prong power cord that grounds the chassis in accordance with NEMA recommendations to protect operating personnel from shock hazards. When plugged into an appropriate power source, the fused power input conforms to applicable safety standards. If it is necessary to operate the unit from a two-prong facility receptacle, the grounding feature should be retained by using a suitable 3-prong to 2-prong adapter and grounding the pigtail lead to the adapter.

TEST PROCEDURE

- a) Connect the power cord to the connector on the rear panel.
Connect plug to AC outlet.
Depress power switch on front panel.
Observe front panel indicators are illuminated.

- b) Allow two minutes for the instrument to warm up, then set the front panel controls as follows:

Identification/Fault Sw.....Pos 1
Drive Current.....LO
Parameter Sw.....V_{BE}
NPN/PNP.....NPN

OBSERVE

“E-B-C” in the Lead window is illuminated.
“Si” and “I” and “V” in the Parameter readout are illuminated.
NPN, PNP, OPEN and SHORT are OFF.

- c) Slowly rotate Identification Switch and observe the following.

SWITCH POS	LEAD WINDOW INDICATORS
POS 1	E-B-C
2	C-B-E
3	B-C-E
4	B-E-C
5	C-E-B
6	E-C-B

OBSERVE

While rotating switch in test above that the following indicators remain OFF.
NPN, PNP, OPEN and SHORT.

- d) Rotate switch to FAULT MODE (Position 7).

OBSERVE

EB__ in the lead window and the OPEN indicators are illuminated.
The SHORT indicator is OFF.

- e) Insert a short length of wire into the transistor socket pin 1 and the other end in pin 2 (emitter and base) shorting the two pins.

OBSERVE

The OPEN indicator is OFF.
The SHORT indicator is illuminated.
Remove wire, indicator should revert to original state.

- f) Move switch to Position 8.

OBSERVE

The __BC lead window indicators are illuminated.
The OPEN indicator is illuminated.
The SHORT indicator is OFF.

- g) Insert wire into pin 2 of the transistor socket and the other end into pin 3 (base, collector) shorting the pins together.

OBSERVE

The OPEN indicator is OFF.

The SHORT indicator is illuminated.

Remove wire, indicators should revert to original state.

- h) Move switch to Position 9.

OBSERVE

The E_C Lead window indicators are illuminated.

The OPEN indicator is OFF.

The SHORT indicator is OFF.

- i) Insert wire into transistor socket pin 1 and the other end into pin 3 (emitter, collector).

OBSERVE

The SHORT indicator illuminates.

Remove wire and indicator should revert to original state.

- j) Move switch to Position 10.

OBSERVE

The Lead window indicator is OFF.

The OPEN indicator is illuminated.

The SHORT indicator is OFF.

- k) Insert wire into pins 1 and 3 shorting pins.

OBSERVE

The OPEN indicator is OFF.

The SHORT indicator is illuminated.

The Lead window indicator is OFF.

Remove wire. This completes the test of the GO/NO-GO section. Rotate Identification switch to Position 1.

The next section will test the Parameter side of the instrument. To do this test you will need a 2N3904 transistor or equivalent.

- a) Verify

a) Parameter Switch set at V_{BE}

b) NPN/PN— Switch set at NPN

- b) Insert a 2N3904 or equivalent silicon transistor into the TO-5 socket observing proper pin configuration.

NOTE

When using the parameter section the DUT must be properly installed in accordance with the front panel labeling. If you are in doubt as to the correct arrangement of the DUT install it in the TO-5 socket on the GO/NO-GO section first to determine lead configuration.

OBSERVE

Display should show:

Si .750 V

This tells us the device is a silicon transistor with a V_{BE} of 0.750 volts.

- c) Move switch to the second position ($I_b = 10 \mu A$).

OBSERVE

The display reads between:

100 to 200

This is a ratio of the collector current to the base current or Beta.

- d) Move switch to the next position ($I_b = 10 \mu A$).

OBSERVE

Display reads between:

100 to 200

- e) Move switch to the next position ($I_b = 10 mA$).

OBSERVE

Display reads approximate 25.

This completes test. Return switch to the V_{BE} position.

Remove transistor and secure test set.

Introduction

The Model 5110 Semiconductor Test Set is a portable general purpose type of instrument designed as an in-circuit or out-of-circuit semiconductor tester. As the name implies, the Semiconductor Test Set has the capability to test most transistors, FET's and diodes, with the only exceptions being triacs, diacs and diode arrays. The instrument is basically divided into two sections, a GO/NO-GO Section and a Parameter Section. Both sections could be used at the same time if required. The only common tie between the two is the power supply.

The Model 5110 circuitry is contained on three (3) printed circuit boards as shown in figure 12.

1. **The Power Supply Board (51105001)** located in the bottom of the instrument.
2. **The Panel Board (51105003)** located behind the front panel.
3. **The Switch Board (511005002)** located on the side of the instrument and positioned vertically.

The three boards are interconnected with ribbon cable, with a 20-pin ribbon cable between the panel board and the power supply board, and a 15-pin ribbon cable between the panel board and the switch board. Addition wiring external to the boards consists of AC wiring to the AC connector, fuse and power switch, and the audio control and output.

The wiring diagram is Drawing No. 51101004.

The schematics are as follows:

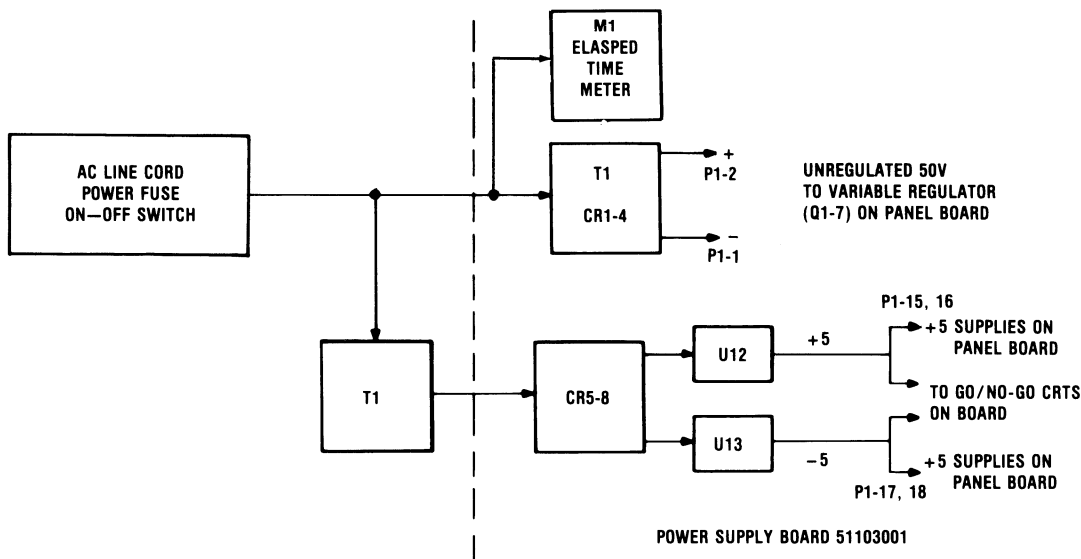
Schematic	Dwg. Number
Power Supply	51101001
Switch Board	51101002
Panel Board, Parameter	51101003, sh 1
Panel Board, GO/NO-Go	51101003, sh 2

Go/No-Go Section

The Model 5110 provides all the circuitry required to effectively determine GOOD or BAD components, determine automatic polarity indications of NPN or PNP devices or N-channel or P-channel FET's. The unit also provides positive lead identification. A GO/NO-GO subsystem block diagram is shown in Figure 5.

Parameter Section

The parameter side of the instrument provides the display and controls necessary for the measurement of transistor beta and FET g_m . It also measures base-emitter voltage ($V_{BE(SAT)}$) and identifies the device-under-test as silicon (Si) or germanium (Ge). A display is provided at the top of the unit to display the readings. The Model 5110 also measures I_{CBO} in five ranges. A switch is provided called "Readout I_{CBO}/V_{CB} " for current/voltage comparisons of collector/base current voltage relationships.



POWER SUPPLY SUB-ASSEMBLY

Figure 4. Power Supply Block Diagram

$V_{BE(SAT)}$ and Si/Ge Identification

When the parameter test switch is in the V_{BE} position (position 1) the D-U-T (transistor) is biased as a saturated switch with $I_b = 1 \text{ mA}$ and $I_c = 10 \text{ mA}$. Figure 6 shows the simplified circuitry for V_{BE} . The digital voltmeter (DVM) reads the saturated base-emitter voltage (V_{BE}). This signal (sense) is also applied to the Si/Ge logic as shown in figure 7 below. The comparators (U4) are LM339, which feature open collector outputs used in the wired — OR configuration. The Ge and Si are appropriately decoded by U3 to light the proper LED bar to display either.

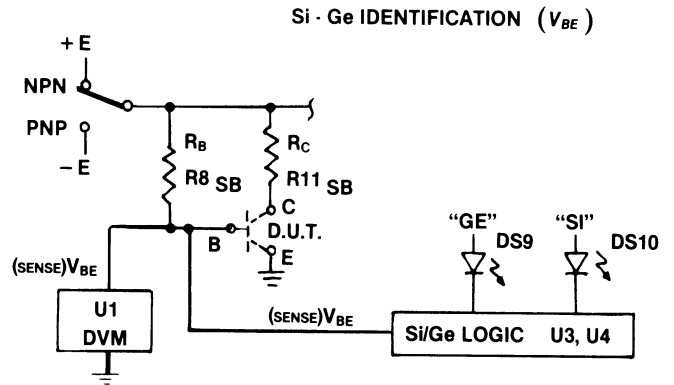


Figure 6. Si-Ge Identification

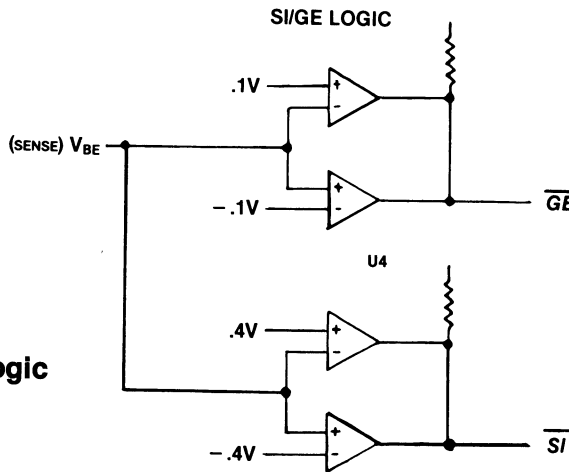


Figure 7. Si/Ge Logic

READ OUT	CONDITION	\overline{GE}	\overline{SI}
BLANK	$ V_{BE} < 2V$	H	H
Ge	$.1V < V_{BE} < .4V$	L	H
Si	$.4V < V_{BE} $	L	L

Beta Measurement

Depending upon the type of transistor under test the bi-directional current source (Q4, Q5, Q6, Q7) either sources or sinks current to the “base” of the D.U.T.

The 2% Duty Cycle Switch Drive (U2, U3) causes the transistor switch (Q1, Q2) to “OPEN” and the FET switch (Q3) to “CLOSE” for 300 μSec every 15 mSec, biasing the D.U.T. “ON”. The voltage across R_{SENSE} (R14-17) is proportional to the D.U.T. collector current. The magnitude of the base drive current is a multiple of ‘1’ allowing the system to be easily scaled (R_{SENSE} is also a multiple of ‘1’).

The use of the 2% duty cycle technique is similar in concept to the methods used by manufacturers to characterize and measure the “pulsed H_{FE} ” specifications.

The FET switch (Q3) and capacitor “C” (C11), constitute a very simple sample and hold circuit for the DVM (U1).

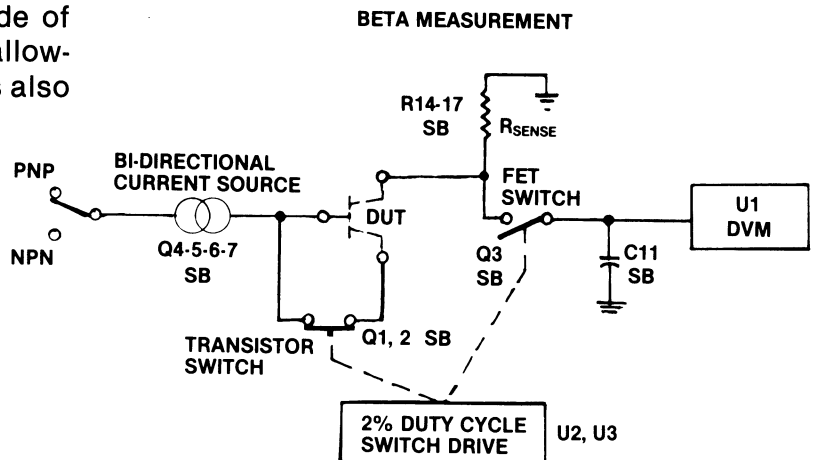


Figure 8. Beta Measurement

g_m Measurement

The FET is biased in a zero gate-source voltage mode, a normal condition for the measurement of g_m . The $V_{gs} = 0$ condition is assured by R_G (R_{12} on the Switch Board) connected between the source and the gate.

A 1kHz sine wave (generated by U5, Q25, Q26, Q27) of 100 mV amplitude is a.c. coupled to the D.U.T.'s (FET) gate. The signal at the drain is:

$$e_d = g_m \cdot e_g \cdot R_o = g_m (100 \text{ mV}) (100 \Omega)$$

$$\text{SO, } g_m = \frac{e_d}{(100 \text{ mV}) (100 \Omega)}$$

The precision rectifier (U1, U2 on the Switch Board), sometimes called an a.c. converter circuit, rectifies, filters and scales e_d to be read by the DVM. Since the precision rectifier is a.c. coupled, it detects only the a.c. signal, thereby providing the dynamic parameter g_m (sometimes called g_{fs} by manufacturers).

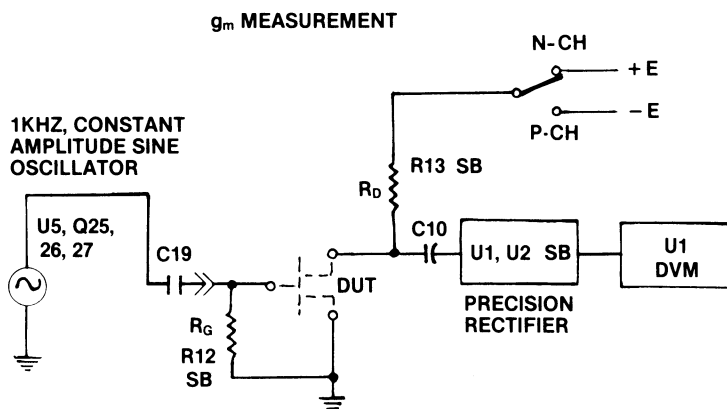


Figure 9. g_m Measurement

I_{CBO} Measurement

The variable power supply, E_{VAR} , (comprised of Q1-7, R59, R60) has a range from 3VDC to 50VDC. A variable current limit "ganged" with the voltage control approximates a constant power function.

i.e., As the voltage output of the supply is increased, the available current is decreased thereby limiting the maximum power from the supply to approximately 50 mW.

The HI-Z Amplifier (U3 on the Switch Board) uses a low-offset operational amplifier in a non-inverting configuration to buffer R_{SENSE} (R_{3-7} on the Switch Board) and provides a gain of 10 to the voltage across R_{SENSE} . Since the highest value of R_{SENSE} is 100K, the input impedance of the HI-Z Amplifier must be at least 2×10^9 ohm to prohibit detectable loading. The DVM (U1) can be switched to read applied voltage or I_{CBO} .

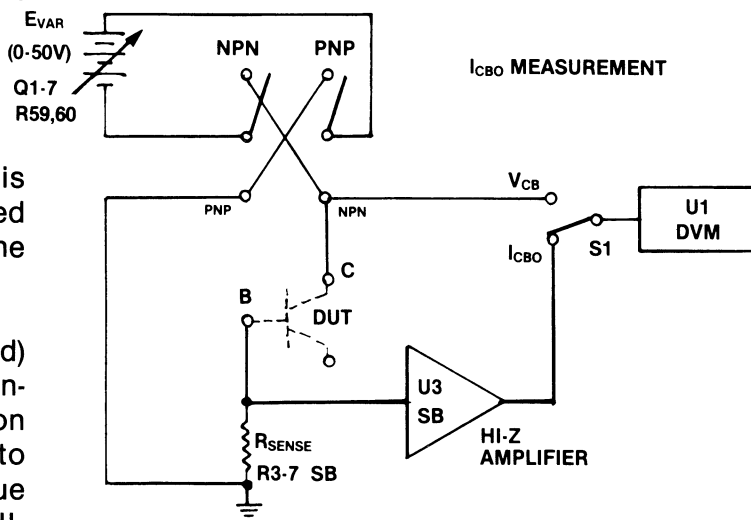


Figure 10. I_{CBO} Measurement

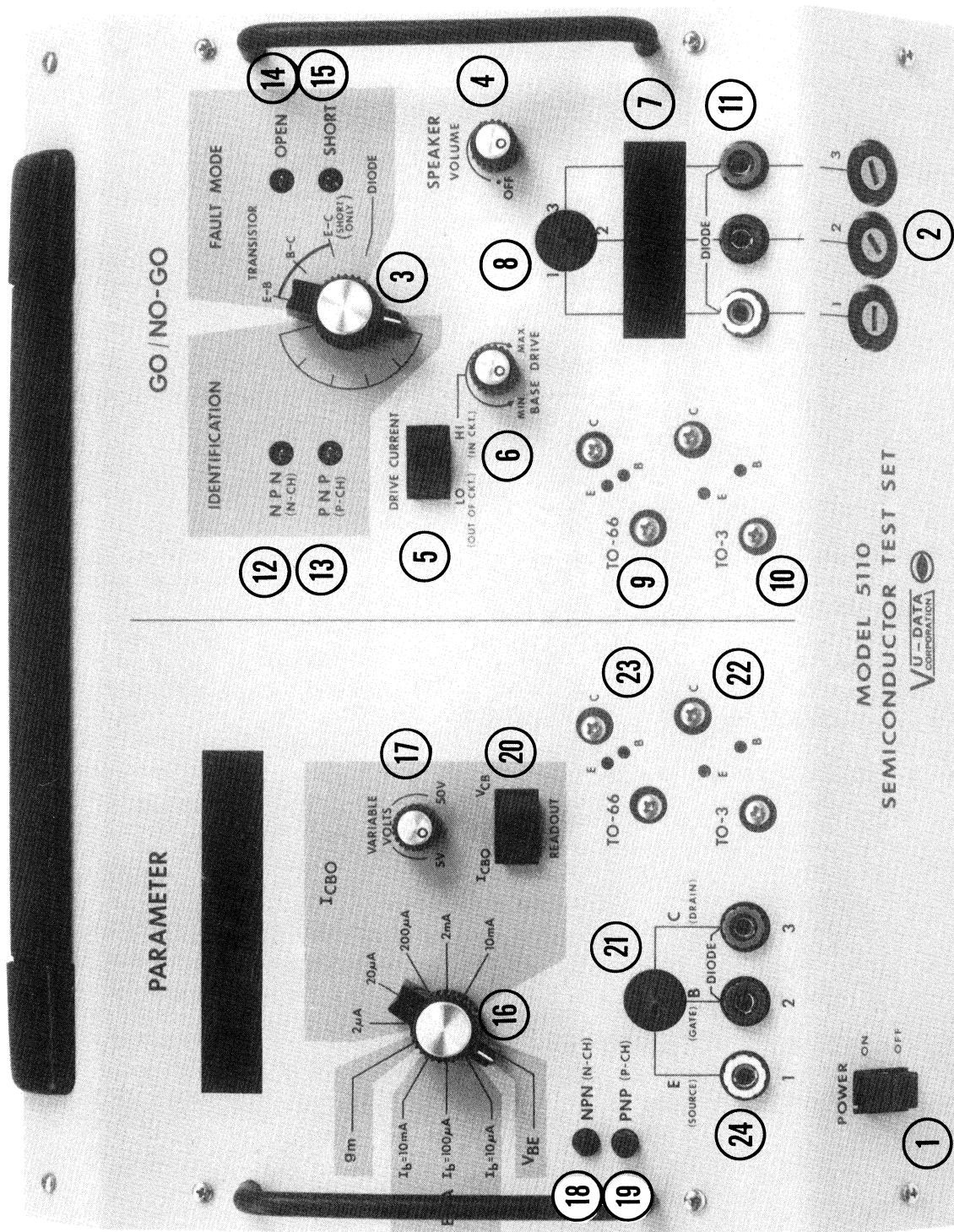


Figure 11. Controls and Indicators

Base Controls

1. POWER ON/OFF SWITCH — Turns unit power on or off.
2. FUSE HOLDERS (3) provide protection on the 3 test leads for the GO/NO-GO SECTION ONLY.

Go/No-Go Section Only

3. IDENTIFICATION/FAULT MODE SWITCH — Selects proper device connections for testing and lead identification. (10 positions).

Position	Identification	
1	E-B-C	Transistor
2	C-B-E	
3	B-C-E LEAD	
4	B-E-C Identification	
5	C-E-B	
6	E-C-B	
7	E-B — Open/short	Transistor Fault Mode
8	— B-C Junction Test	
9	E — C Short only Junction Test	
10	C — — or Open/short and — — C Cathode Identify	Diode Test

4. AUDIO KNOB — turns audio tone ON/OFF and adjust volume to desired level in GO/NO-GO SECTION.
5. LO/HI Switch — Selecting drive level required for the identification test.
6. BASE DRIVE KNOB — In HI, varies Base Drive current from approximately 10 mA (min) to approximately 100 mA (max).
7. LEAD WINDOW — 7 segment displays (3) provide lead identification to sockets.
8. TO-5 TEST SOCKET — Out of circuit tests can be performed by inserting the semiconductor into socket. The terminals are internally connected in parallel with those of Test lead sockets. (11)
9. TO-3 Test Socket — Same.
10. TO-66 Test Socket — Same.

11. Test Lead Sockets (3) — These sockets are receptacles for the test leads provided with the STS. Fused inputs. Protect against connection to a live circuit.
12. NPN INDICATOR — LED indicator lights when an NPN transistor or N-channel FET test GOOD.
13. PNP INDICATOR — LED indicator lights when a PNP transistor or P-channel FET test GOOD.
14. OPEN FAULT INDICATOR — LED indicator lights to indicate an OPEN condition in DUT.
15. SHORT FAULT INDICATOR — LED indicator lights to indicate a SHORT condition in DUT.

Parameter Test Section

16. PARAMETER TEST SWITCH — 10 position rotary switch for selection of test par.

Position

1	$V_{BE(SAT)}$	} Beta
2	$I_b = 10\mu A$	
3	$I_b = 100\mu A$	
4	$I_b = 10mA$	
5	$20m\Omega - g_m$	} I_{CBO}
6	$2\mu A$	
7	$20\mu A$	
8	$200\mu A$	
9	$2mA$	
10	$10mA$	

17. VAR VOLTS KNOB — In I_{CBO} , varies the voltage applied to DUT from 5 to 50V, also varies the current limiter from 10mA at 5V to 1mA at 50V.
18. NPN PUSHBUTTON —
19. PNP PUSHBUTTON — MUST be set to type of DUT for all parameter tests.
20. I_{CBO}/V_{CB} ROCKER SWITCH — changes display to a readout of volts applied or leakage current.
21. TO-5 TEST SOCKET — Out of circuit tests can be performed by inserting the semiconductor into socket. The terminals are internally connected in parallel with those of Test lead sockets. (24)

22. TO-3 Test Socket (see 21).
23. TO-66 Test Socket (see 21).
24. Test Lead Sockets — can be used with mini-grabber to connect to a device with short or bent leads.

PARAMETER

Si	1	0	0	0	V	mV
Ge	1	0	0	0	μ A	mA

Display

Si — In V_{BE} , junction measured is silicon device.

Ge — In V_{BE} , junction measured is germanium device.

V — Volts (V_{BE}), (I_{CBO} -volts).

mV — Milli-MHOS (g_m).

μ A — Micro Amps ($A \times 10^{-6}$) I_{CBO} .

mA — Milli Amps ($A \times 10^{-3}$) I_{CBO} .

3½ digit LED display with floating decimal point.

A display of 1-blank-blank-blank indicates an overrange condition.

— CAUTION —

NEVER APPLY POWER TO DEVICE OR P.C. BOARD BEING TESTED WHILE CONNECTED TO THE MODEL 5110 STS

ALL STS TESTING OF IN-CIRCUIT COMPONENTS MUST BE PERFORMED WITH NO CIRCUIT POWER APPLIED

Introduction

The 5110 STS can be considered as three separate instruments with three levels of testing of a semiconductor.

Level One is a GOOD/BAD indication using the GO/NO-GO switch in positions one through six (position 10 for diodes).

Level Two is a fault analysis of open-short conditions using the GONO-GO switch in positions 7, 8, 9 (position 10 for diodes).

Level Three is for parameter measurements such as V_{BE} , I_{CBO} or Beta using the parameter section of the 5110.

Level One tests can be performed in or out of circuit, and identify device polarity (NPN or PNP) and lead configuration as well as a GOOD/BAD indication.

Level Two tests must be conducted with the device connected in the proper lead configuration.

Level Three tests are out-of-circuit tests only, and the device must be connected with the proper lead configuration and device polarity

LEVEL 1 TESTING — GO/NO-GO

Introduction

The following operational steps are provided for Basic GO/NO GO testing of transistors, FET's, Diodes and SCR's. When testing always start with the Indicator switch in Position 1 with the Drive switch in LO. Turn Indicator switch in the CW motion to Position 6 slowly — if you don't get a NPN or PNP light, switch the Rocker switch to HI, set BASE Drive to HI, and move the Identification switch CCW from 6-1. If you fail to get an NPN or PNP light then you can assume the device is defective.

A. Transistors (Power and Signal Transistors)

1. Set Power rocker switch to — ON
Set a Drive rocker switch to — LO
Set Identification switch to — POSITION 1
Set Audio Knob — as desired.

2. Insert the transistor-under-test in the appropriate test socket (TO-3, 5 or 66) or connect the mini-grabber test leads or 3-pin test probe to the device-under-test (DUT).

NOTE

If unsure of the DUT basing, leads can be connected to the DUT in any order, but test leads must be plugged into their respective color test lead jack. (yellow-green-blue)

3. Move the Identification test switch slowly CW through its six positions until one of the two red LED's (NPN or PNP) glows. A tone will also be heard if the Audio has been turned on. Identification is determined by the lamp that is glowing (NPN/PNP). In the LO-position most transistors will only test GOOD in one Identification test switch position. When in this position the leads of the transistor will be identified in the LED display as:

E — Emitter
B — Base
C — Collector

4. If you fail to obtain a GOOD indication as the Identification test switch is slowly moved CW through its six positions, in LO drive, then the D.U.T is one of the following:
 - a) Transistor with high leakage or very low gain.
 - b) Device with shorted/open elements.
 - c) FET Device that will not test in LO drive.
 - d) A device requiring a high base drive voltage such as a Darlington Power transistor.
 - e) An in-circuit device with excessive circuit shunting.
5. Set the Drive Current rocker switch to HI and the BASE DRIVE pot to MAX. Rotate the Identification switch CCW from Position 6 towards Position 1, checking for a "GOOD" (NPN or PNP) indicator to light.

NOTE

In the HI DRIVE, MAX BASE DRIVE mode, a good transistor with a high reverse beta will show "GOOD" in two adjacent switch positions with the E-C leads reversed (example EBC = CBE). The device is still correctly identified as GOOD or BAD, and NPN or PNP.

To identify the E-C leads, switch back and forth between the two positions while reducing BASE DRIVE until the NPN or PNP light will light in only one position.

B. FET's (Power or Signal FET's)

1. Set Power rocker switch to — ON
Set Drive rocker switch to — HI
Set Base Drive to — MAX
Set Identification switch to — POSITION 1
Set Audio Knob — to desired position
2. Insert device into appropriate socket (TO-3, 5 or 66) or connect the three test leads (in any order) to the FET.

NOTE

The three test leads must be plugged into their respective color test lead jack (Yellow-Green-Blue).

3. Move Identification test switch slowly CW from Position 1 until a GOOD FET LED is illuminated and a tone is heard.
4. The base (B) indicator shown in the display is the GATE. S-D leads are not identified.

NOTE

J-FET's will indicate GOOD in two adjacent test positions which have the same Base position. (Most J-FET's are symmetrical).

5. If you fail to obtain a GOOD indication, the FET-under-test is defective.

C. Diodes

1. Set Power rocker switch to — ON

Set Drive rocker switch to — LO
Set Identification switch to — POSITION 10
Set Audio Knob — to desired level.

2. For cathode lead identification connect diode to the Blue and Yellow test leads. If the diode is GOOD the Cathode will be identified with a "C". If the diode is a BAD diode, the "Open" or "Short" LED will illuminate. If the diode is GOOD a tone will be heard.

D. Zener Diodes

(Same as Diodes).

E. SCR's

1. Set Power Switch to — ON
Set Drive Switch to — HI
Set Identification Switch to — POSITION
2. Connect the three test leads (in any manner) to the three leads of the SCR under test.
3. Move the Identification test switch CW through the six positions.

NOTE

With most SCR's, the NPN LED will illuminate in one test position and the PNP will illuminate in another test position. Some medium and high voltage SCR's may provide only an NPN indication.

4. The SCR is GOOD if an NPN indication is obtained (the additional PNP indication, if obtained, only confirms the device is an SCR.)
5. With the Identification test switch in the position that provides the NPN indication, the lead identification will provide
 - B — is the gate lead
 - E — is the cathode lead
 - C — is the anode lead.

6. If the NPN fails to light in any of the six positions the SCR is defective. A "GOOD" indication verifies that the SCR can be triggered into conduction.

LEVEL 2 TESTING — FAULT MODE

A. Transistors

The fault mode test is for testing transistors with known lead arrangements. Plug-in transistor into the test socket or use test leads in the EBC arrangement i.e.,

Yellow Lead — Emitter (1)	} TO-5
Green Lead — Base (2)	
Blue lead — Collector (3)	

Fault Switch Position 7 tests E-B Short/open
 8 tests C-B Short/open
 9 tests E-C Short

If there is a fault then short or open light will illuminate. During tests the following indicators will be illuminate.

Fault Switch Position	7 "E" "B"
	8 "B" "C"
	9 "E" "C"

NOTE

*In the Fault Mode, in order to test a transistor the lead arrangement **MUST** be known and transistor properly installed in order for the testing to proceed.*

B. Diodes

- Set Power rocker switch to — ON
 Set Drive rocker switch to — LO
 Set Identification switch to — POSITION 1 0
 Set Audio Knob — as desired.
- For cathode lead identification connect diode to the Blue and Yellow test leads. If the diode is GOOD the Cathode will be identified with a "C". If the diode is a BAD diode, the "Open" or "Short" LED will illuminate. If the diode is GOOD a tone will be heard.

LEVEL 3 TESTING — PARAMETER

The heart of the parameter section is the Parameter Test Switch, a ten position rotary switch used to select the test parameter and the Multifunction Parameter display which provides the appropriate readouts.

NOTE

*When testing semiconduction devices in the Parameter section, lead configuration **MUST** be known and leads properly installed in appropriate test sockets. (i.e., B is base, E is emitter, and C is collector.)*

Also, the type of device, NPN or PNP must be known and the proper pushbutton selected.

If in doubt about either of these functions, use the GO/NO-GO section to determine proper lead configuration and device type.

A. Parameter Testing

- TRANSISTORS (Power and Signal)
 - Set Power Rocker Switch to ON
 - Set Parameter Switch to V_{BE}
 - Set NPN or PNP Switch as required.
 - Allow test set to warmup for 2 minutes before using.
- SWITCH POSITION 1

Install DUT in proper socket (TO-5, TO-3, TO-66) taking extreme care to properly arrange leads.

OBSERVE
 The display shall read the following:

Si or Ge —	silicon or germanium depending on the device.
.XXX —	a three digit display of the value of V_{BE}
V —	indicating the reading is in volts

So, we know that the device has a V_{BE} of a certain value, that is either a silicon or germanium device and that it is a NPN or a PNP.
- Rotate Parameter Switch one position. The switch is now in the LO BETA mode ($I_b \approx 10\mu A$).

OBSERVE

The display will show only a three digit display—this is a ratio of the collector current to the base current or BETA.

The next two switch positions are also for Beta.

Position 3	MED BETA	$I_b = 100 \mu A$
Position 4	HI BETA	$I_b = 10mA$

NOTE

Care should be used in selecting the Beta range to test the transistor. It is possible to damage small signal transistors in the HI range. However, testing of power transistors in the LO range, although it will not damage the device, will result in a reading of little value as power transistors are not designed to operate at low current levels.

The I_{CBO}/V_{CB} Readout rocker switch will vary the readout display from leakage current to voltage applied.

With the I_{CBO}/V_{CB} switch in the V_{CB} mode you can adjust the voltage applied with the variable voltage knob from 5 to 50 volts, switch to I_{CBO} and read the leakage current at the selected voltage level. Or, select the I_{CBO} and switch to V_{CB} to observe the voltage level at which it occurs.

d) Position 5, g_m Reading (for FET's)

Set the NPN/PNP Switch to the proper type of device N-ch or P-ch, install the FET in the appropriate test socket with the lead configuration as follows:

FET	TRANSISTOR
Drain	Collector
Gate	Base
Source	Emitter

The display will show a reading of g_m and the $m\Omega$ lights will indicate the reading is in mill-mhos.

NOTE

Most plastic FET's have the GATE lead on the right side when facing the flat side with the leads down and the SOURCE in the middle, although there are exceptions.

In most Junction FET's, the source and drain can be interchanged without adverse effects.

e) Rotate parameter switch to Position 6 (I_{CBO}). Positions 6 through 10 provide a range from $2 \mu A$ through 10 mA as required.

Set NPN/PNP Switch to proper type of device. Install device in proper test socket observing correct lead configuration.

The display will read a three digit readout and indicate μA or mA depending on the parameter selected.

General

The Model 5110 Semiconductor Test Set uses a high-current, low duty cycle pulse technique to test transistors. A six-position switch is used to enable the user to identify the leads of the D.U.T. in most in-circuit tests and all out-of-circuit tests. Circuitry is provided for out-of-circuit measurement of transistor beta and FET g_m , plus the testing of high current devices at rated current (up to 2 amperes) without over-dissipation and leakage.

At last there is a simple, sure and inexpensive way to detect defective components in-circuit or out-of-circuit, without the need of circuit power.

Selecting Drive Current

The STS provides two ranges of operation in the GO/NO-GO Section to facilitate a greater range of testing.

- a) LO RANGE — In the LO range the drive currents are as follows:

base drive 1mA
 collector 50mA

most testing will be accomplished in this range.

- b) HI RANGE — In the HI range the drive currents are as follows:

base drive 10mA to 100mA
 collector 200mA

Fault Mode

The STS will allow fault isolation of a device in almost all cases when used properly. There are three fault positions. The first position provides for testing of emitter-base open/short. The second position provides testing of base collector junction, the third position is for emitter-collector junction short test. The fourth position is for testing open or short condition or diodes, if good the first or third LED indicator will light showing the location of the cathode of the diode under test.

The STS can be used to test virtually any component out-of-circuit, but where its real value shows is its ability to test devices in-circuit, transistors, FET's, diodes and other devices can be evaluated while installed on the printed circuit board, reducing the time required to locate defective parts while eliminating circuit board damage caused by removal and replacement of devices.

CAUTION

ALL TESTING OF IN-CIRCUIT COMPONENTS MUST BE PERFORMED WITH NO CIRCUIT POWER APPLIED. DO NOT ATTEMPT TO USE THE STS IN A LIVE CIRCUIT.

Application Notes

The following pages of application notes provide general information on various devices. These are provided for your help in determining what type of device and the lead determination.

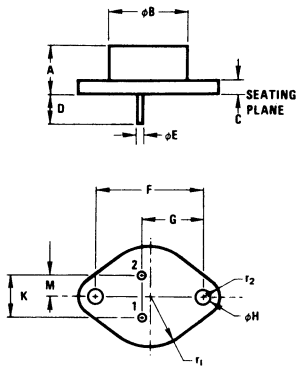
WARNING

Never apply power to device or P.C. Board being tested while connected to the Model 5110 Semiconductor Test Set.

All STS Testing of in-circuit components must be performed with NO CIRCUIT POWER applied and all capacitors discharged.

Package Outlines

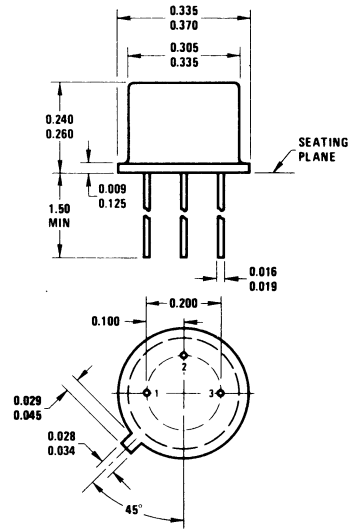
TO-3



Terminal Connections
 Pin 1 - Ground
 Pin 2 - Output
 Case - Input

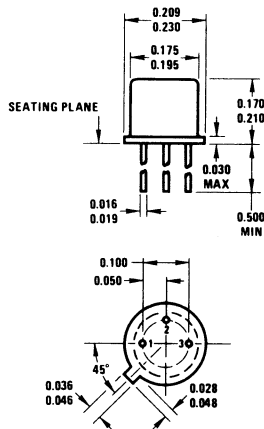
SYMBOL	INCHES	
	MIN	MAX
A	.250	.450
ϕE	.038	.043
ϕB		.875
K	.420	.440
M	.205	.225
C		.135
D	.312	
ϕH	.151	.161
F	1.177	1.197
r_1		.525
r_2		.188
G	.655	.675

TO-5



PIN	T
1	E
2	B
3	C

TO-18

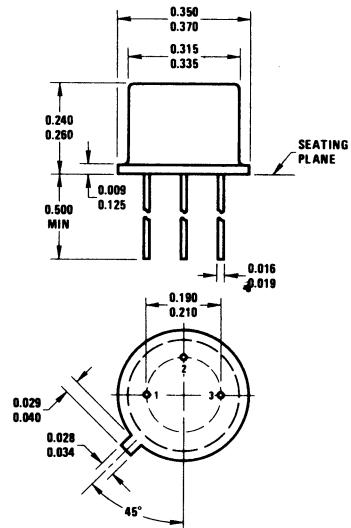


PIN	T
1	E
2	B
3	C

PIN	FET N
1	S
2	D
3	G

PIN	FET P
1	S
2	G
3	D

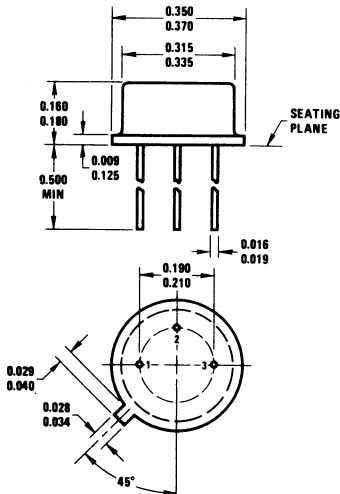
TO-39



PIN	T
1	E
2	B
3	C

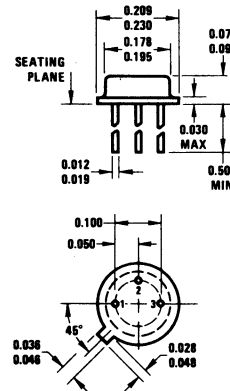
TO-39

LO-PROFILE



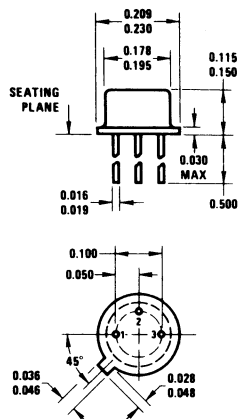
PIN	T
1	E
2	B
3	C

TO-46



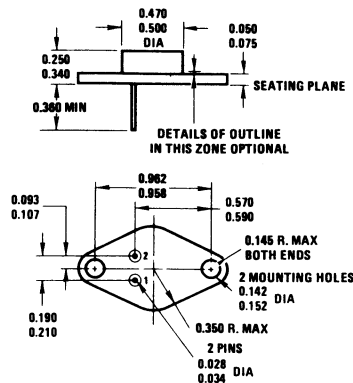
PIN	T
1	E
2	B
3	C

TO-52



PIN	T	FET
1	E	S
2	B	D
3	C	G

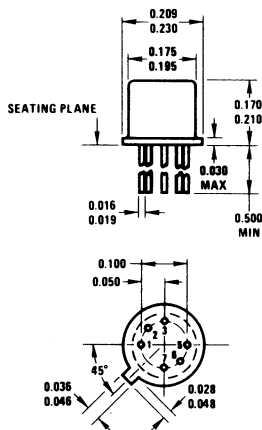
TO-66



DETAILS OF OUTLINE IN THIS ZONE OPTIONAL

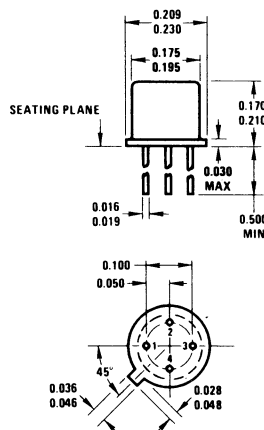
PIN 1 - BASE
PIN 2 - EMITTER
CASE - COLLECTOR
MOUNTING FLANGE - COLLECTOR

TO-71



PIN	T	FET
1	E	S1
2	B	D1
3	C	G1
5	E	S2
6	B	D2
7	C	G2

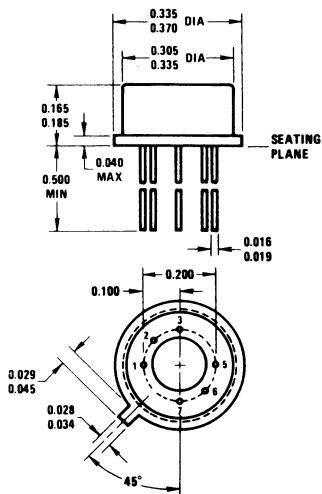
TO-72



PIN	T	FET N
1	E	S
2	B	D
3	C	G
4	GND	CASE

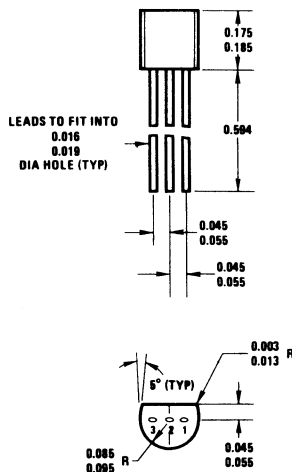
PIN	T	FET P
1	B	S
2	E	G
3	C	D
4	GND	CASE

TO-78



PIN	T	FET
1	C	S1
2	B	D1
3	E	G1
5	E	S2
6	B	D2
7	C	G2

TO-92



PIN	(Std)	
	T	FET
1	C	G
2	B	S
3	E	D

PIN	FET	
	T	FET
1	C	G
2	E	D
3	B	S

PIN	FET	
	T	FET
1	B	S
2	C	G
3	E	D

Tips for Using the Model 5110

1. GERMANIUM TRANSISTORS — Nearly all germanium transistors come in metal cases, either in the tubular type with flexible leads or in the standard TO-5 package.
2. POWER TRANSISTORS — In TO-3 or TO-5 or stud packages can be either germanium, silicon or FET. Two or three digit 2N-numbers are mostly germanium.
3. The TO-66 power transistors and the plastic tab packages are nearly always silicon. The collector is usually, **but not always**, connected to the mounting tab and the center lead. Verification can be accomplished by a continuity check between the collector pin and the mounting tab.
4. The Base lead of most modern plastic-type transistors is either the center lead or the right-hand lead when facing the flat side with the leads down. In the latter case, the collector lead is the center lead.
5. FETS — most plastic FET's have the GATE lead on right side when facing the flat side with the leads down and the GATE lead on the right side when facing the flat side with the leads down and the SOURCE in the middle, but there are exceptions. In nearly all junction FET's, the source and drain can be interchanged without adverse effects.
6. POWER FETS — Power FET's in TO-3 packages generally have lead configurations similar to bipolar transistors, as follows:

FET	TRANSISTOR
DRAIN	COLLECTOR(CASE)
GATE	BASE
SOURCE	EMITTER

7. GERMANIUM SIGNAL DIODES — usually can be identified by their transparent hollow glass cases with either three or four color bands, or numbers printed on them.
8. SILICON DIODES — are usually painted because silicon is light sensitive and must be protected.
9. All transistors will have some gain with the collector and emitter leads interchanged, with the exception of Darlingtons.

10. There are certain semiconductor devices that look like transistors which the Model 5110 **cannot** test. These include: Triacs, diacs and diode arrays.

Glossary of Terms

$V_{BE(SAT)}$

Base-Emitter Saturation Voltage.

The base-emitter voltage measured in the common-emitter connection at a specified collector and base saturation currents.

Beta

The ratio of the collector current to the base current of a bipolar transistor, commonly referred to as either the common-emitter current gain or the current amplification factor.

I_{CBO}

Collector cutoff current.

The DC current into the collector terminal when it is biased in the reverse direction with respect to the base terminal and the emitter terminal is open-circuited.

V_{CB}

Voltage/Collector to Base.

Voltage, dc or average between the collector and the base. (Stated in terms of the polarity at the terminal indicated by the first subscript.)

$g_m (m \Omega)$

Common-source forward transconductance (g_{fs}).

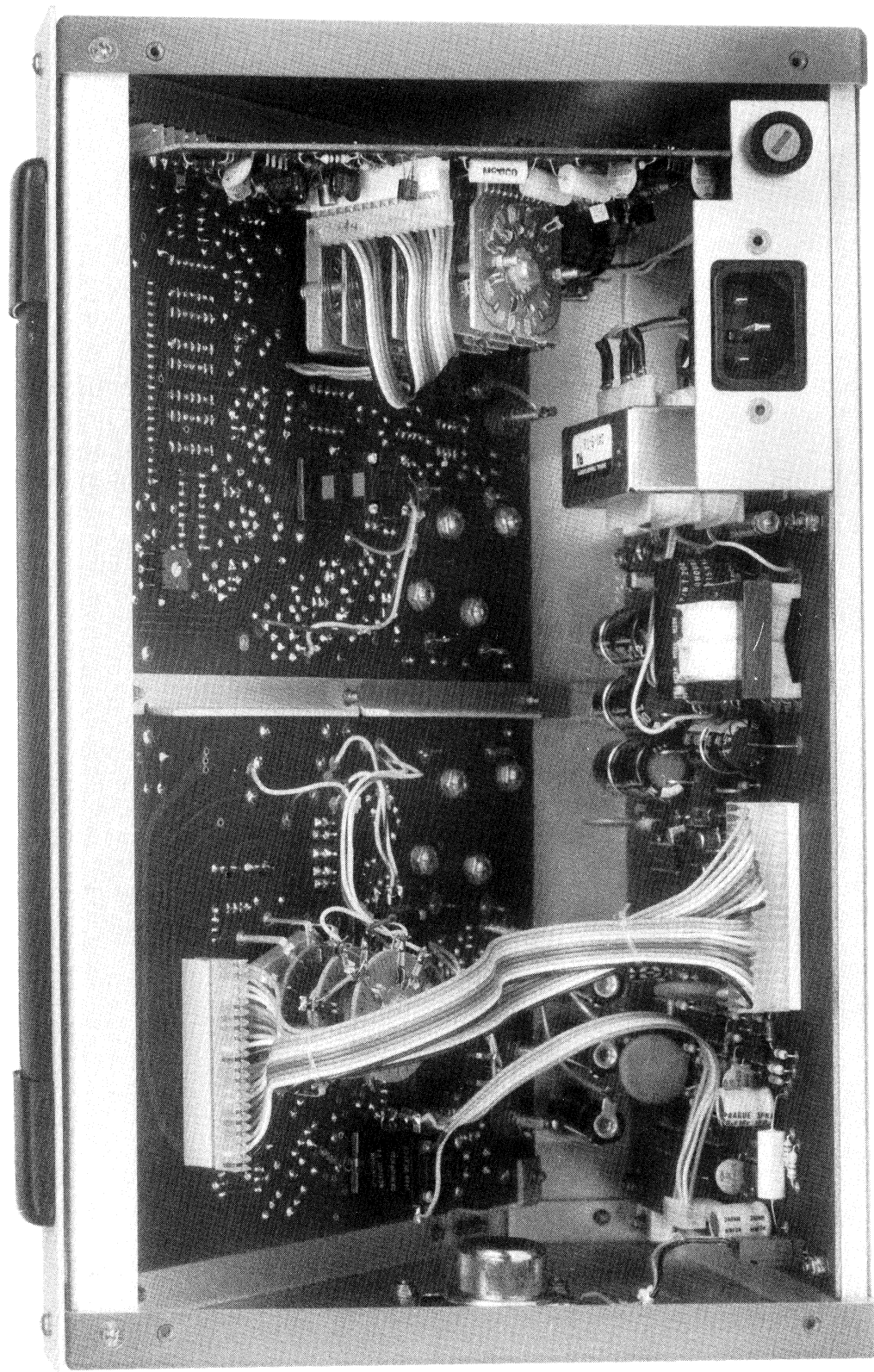


Figure 12. Rear View w/Cover Removed Showing Location of PC Boards

General

This chapter of the manual contains the information necessary for preventive maintenance, troubleshooting, corrective maintenance and calibration.

Preventive Maintenance

Preventive maintenance shall consist of periodic cleaning, inspecting, tightening, and recalibrating the instrument at a regular interval. This will keep the instrument at its operational and appearance peak.

CAUTION

Avoid the use of chemical cleaning agents such as MEK, laquer thinner, or strong acids or alkali. These solvents will cause paint removal, deterioration of switches and melting of plastic parts.

The accumulation of dirt or dust should be removed as noticed. The frequency of cleaning will depend on the environment in which the instrument is used. Loose dirt on the outside may be removed with a soft cloth or a dry brush. A diluted household cleaner (non-abrasive) may be used. Cleaning of the inside of the unit should be accomplished with LOW pressure air or a soft brush. Cleaning of the unit should precede the calibration, since the cleaning procedure could alter the settings.

CAUTION

ALWAYS remove the AC Power Cord from the connector on the rear panel before removing back and bottom covers. The interior of this instrument contains voltage levels which could be hazardous to your health. AC power lines are exposed when the covers are removed.

Inspection

After cleaning the instrument, a thorough inspection of the components on the circuit boards can reveal areas where troubles could occur. Look for the obvious, like components with discolored markings from overheating. Check wiring for chafing. Removal of circuit

boards is not recommended unless part replacement is required. Check that all screws are tight and all plugs and jacks are fully engaged.

Troubleshooting

Most of the problems resulting from a malfunction will be caused by the failure of an electronic component or a defective mechanical problem. Verify the obvious first. Check power, switch settings, etc., to verify proper inputs.

Standard test equipment can be used to isolate down to the component level. The use of the Functional Checkout Procedure on page 11, will verify the operation of the various controls.

Before starting troubleshooting a thorough knowledge of the operating procedure and the schematics will be of value.

Troubleshooting Precautions

WARNING

Before removing the covers for trouble shooting, read and observe the following precautions. Circuits are exposed which could become hazardous if not handled properly.

- a) Always remove the power cord from the instrument BEFORE removing or replacing top and bottom covers.
- b) When working on the instrument with the covers removed and the power cord connected, AC power is present at some points on the printed circuit board even with power "OFF".
- c) Do not unplug any circuit boards or DIP connectors with power applied to the instrument.

Parts Identification

The Model 5110 is divided into three sub-assemblies as follows:

1. Power Supply Sub-Assembly (51105001)
2. Switch Board Sub-Assembly (51105002)
3. Panel Board Sub-Assembly (51105003)
4. Power Supply Assembly (51105004)

These modules comprise the sub-assemblies that assemble into:

- a) Chassis (51105005)
- b) Final Assembly (51105006)

These assemblies and sub-assemblies are tabulated in Table 1.

Table 1. Model 5110 Assemblies

Table	Assembly Number	Assembly
2	51105001	Power Supply Board Sub-Assy
3	51105002	Switch Board Sub-Assy
4	51105003	Panel Board Sub-Assy
5	51105004	Power Supply Assy
6	51105005	Chassis
7	51105006	Final Assembly

In addition there are three tables which contain parts lists of the various sub-assemblies. Each part is identified by a drawing reference designator, manufacturer's part number, description of part, manufacturer, and Vu-Data part number.

Replacement Parts

Individual components are generally "off-the-shelf" and are available at local suppliers or may be ordered from Vu-Data Corporation. If other parts are substituted, verify that the part is a direct replacement, or performance and/or calibration difficulties may arise.

Calibration Procedure

The following procedure provides the information necessary for technical personnel to calibrate the Model 5110. This calibration should be performed at periodic intervals to certify proper operation.

CALIBRATION PROCEDURE

Test Equipment Required

- a) A Digital Multimeter.
- b) A known good 2N3904 silicon transistor or equivalent.

Preliminary Control Settings

Remove the AC power cord. Remove the rear/bottom cover. Plug in the AC line cord on the rear of the instrument and turn the instrument "ON", allow ten (10) minutes warm-up before starting calibration procedure.

Set the front panel controls as follows.

1. Power Sw.....ON
2. Identification/Fault Sw.....Pos. 1
3. Drive Current Sw.....LO
4. Parameter Test Sw..... V_{BE}
5. NPN/PNP Sw.....NPN

Verify that the following indicators are illuminated:

1. The EBC indicator is illuminated in the GO/NO-GO section.
2. The Si and V LED's are illuminated.
3. The DVM should read 1, showing an over-voltage condition.

Power Supply Calibration

1. Verify —
 - a) Parameter Sw set at V_{BE}
 - b) Ident/Fault Sw at POS. 1
 - c) Nothing is plugged into any of the test sockets
2. Turn instrument over face down on protective handles.
3. Locate R3 (+5V CAL) and R4 (−5V CAL) on the power supply board on the bottom side of the instrument (which is now facing you.) Locate large pad to left of resistor R4 — this is common.

4. Attach DMM to +5V at top center of board, adjust R3 for $+5.000V \pm 50mV$.
5. Attach DMM to -5V at top center of board, adjust R4 for $-5.000V \pm 50mV$.
6. Remove DMM — Set instrument in the upright position.
7. Plug the 2N93904 or equivalent silicon transistor into the PARAMETER TEST SOCKET. Verify NPN/PNP switch is in the NPN position.

Readout should be approximately .750 with the Si and V LED's illuminted.
8. Connect the DMM LO lead to the emitter of the transistor. The HI lead to the base lead.
9. On the panel board adjust R28 (located top-center on the board) until the parameter readout on the STS equals the readout on the DMM.

This concludes the calibration procedure. Return all controls to normal/off configuration. Remove power line cord. Replace the rear/bottom cover. Reconnect power cord. Unit is now ready for use.

— CAUTION —
**NEVER APPLY POWER TO DEVICE OR
P.C. BOARD BEING TESTED WHILE
CONNECTED TO THE MODEL 5110**
**ALL STS TESTING OF IN-CIRCUIT
COMPONENTS MUST BE PERFORMED
WITH NO CIRCUIT POWER APPLIED**

Table 2. Parts List (Power Supply Board Sub-Assy 51105001)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51103001	Etched Circuit Board	Vu-Data	51103001
CAPACITORS				
C1	TLB2A101M	100uf, 100V	Nichicon	6-87001
C2	ULBIE222M	Elect, 2200uf, 25V	Nichicon	6-87002
C3	ULBIE222M	Elect, 2200uf, 25V	Nichicon	6-87002
C4	CACO3Z5U104 Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C5	CACO3Z5U104- Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C6	ULBIE222M	Elect, 2200uf, 25V	Nichicon	6-87002
C7	ULBIE222M	2200uf, 25V	Nichicon	6-87002
C8	CACO3Z5U104- Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C9	513D156M063AA4	Elect 15uf, 63V	Sprague	6-87156
C10	A11A105J	MYLAR, 1uf, 50V	Bishop	6-46105
C11	CACO3Z5U104- Z050ALTR	Mono. .1uf, 50V	Corning	6-36104
C12	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C13	503D107F016NB	Elect, 100uf, 16V	Sprague	6-87107
C14	CACO3Z5U104- Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C15	A11A273J	MM, .027uf, 50V	Bishop	6-46273
C16	CACO3Z5U104- Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C17	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C18	503D107F016NB	Elect, 100uf, 16V	Sprague	6-87107
C19	CACO3Z5U104- Z050ALTR	Mono .1uf, 50V	Corning	6-36104
C20	5HKD10	CD, .001uf,	Sprague	6-20102
C21	5HKD10	CD, .001uf,	Sprague	6-20102
C22	5HKD10	CD, .001uf,	Sprague	6-20102
C23	30GA-T39	DM, 390Pf,	Sprague	6-29391
C24	5GA-D50	CD, .001uf,	Sprague	6-29502
C25	5GA-D50	CD, .001uf,		6-29502
C26	H11A153J	MYLAR, .015uf, 50V	Bishop	6-46153
C27	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C28	503D107F016NB	Elect, 100uf, 16V	Sprague	6-87107
C29	CACO3Z5U104- Z050ALTR	.1uf, 50V	Corning	6-36104
C30	513D156M063AA4	Elect, 15uf, 63V	Sprague	6-87156
C31	DD-1032	CD, .01uf, 1KV	Centralab	6-29053
CONNECTOR				
P1	2-640454-0	Header, 20 PIN	AMP	2-24060
P2	640454-5	Header, 5 PIN	AMP	2-24042
P3	1100-8-102-01	Header, 2 PIN	El. Sn. Comp.	2-24031

Table 2. Parts List (Power Supply Board Sub-Assy 51105001) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
DIODES				
CR1	IN4004	Diode, Pwr	Motorola	3-14004
CR2	IN4004	Diode, Pwr	Motorola	3-14004
CR3	IN4004	Diode, Pwr	Motorola	3-14004
CR4	IN4004	Diode, Pwr	Motorola	3-14004
CR5	IN4004	Diode, Pwr	Motorola	3-14004
CR6	IN4004	Diode, Pwr	Motorola	3-14004
CR7	IN4004	Diode, Pwr	Motorola	3-14004
CR8	IN4004	Diode, Pwr	Motorola	3-14004
CR9	IN914	Diode, Signal	ITT	3-10914
CR10	IN914	Diode, Signal	ITT	3-10914
CR11	IN914	Diode, Signal	ITT	3-10914
CR12	IN914	Diode, Signal	ITT	3-10914
CR13	MR501	Diode, Pwr	Motorola	3-10501
CR14	MR501	Diode, Pwr	Motorola	3-10501
CR15	MR501	Diode, Pwr	Motorola	3-10501
CR16	MR501	Diode, Pwr	Motorola	3-10501
INTEGRATED CIRCUITS				
U1	NE555	TIMER, 555	RCA	3-30555
U2	NE555	TIMER, 555	RCA	3-30555
U3	MC14011BCP	QUAD 2 INPUT NAND	Motorola	3-34011
U4	MC14013BCP	Dual D Flip-Flop	Motorola	3-34013
U5	UA339PC	Quad Comparator	Motorola	3-30339
U6	MC14013BCP	Dual D Flip-Flop	Motorola	3-34013
U7	MC14011BCP	Quad, 2 Input NAND	Motorola	3-34011
U8	MC14011BCP	Quad, 2 Input NAND	Motorola	3-34011
U9	NE555	Timer, 555	RCA	3-30555
U10	MC14023BCP	3-Input NAND	Motorola	3-34023
U11	MC14011BCP	Quad, 2 Input NAND	Motorola	3-34011
U12	LM317MP	Regulator	National	3-30317
U13	LM337MP	Regulator	National	3-30337
U14	T-200-4	Meter Regulator	Fredericks	3-32004
RESISTORS				
R1	RN55D2490F	MF, 249 ohm, 1/8W, 1%	Allen Bradley	5-51134
R2	RN55D6340F	MF, 634 ohm, 1/8W, 1%	Allen Bradley	5-51173
R3	33865-1-201	VAR, 200 ohm, PC Mount	Bourns, Inc.	5-73201
R4	33865-1-201	VAR, 200 ohm, PC Mount	Bourns, Inc.	5-73201
R5	RN55D7320F	MF, 732 ohm, 1/8W, 1%	Allen Bradley	5-51173
R6	RN55D2490F	MF, 249 ohm, 1/8W, 1%	Allen Bradley	5-51134
R7	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R8	RCR07G470JR	CC, 47 ohm, 1/4W, 5%	Allen Bradley	5-10470
R9	RCR07G823JR	CC, 82K ohm, 1/4W, 5%	Allen Bradley	5-10823
R10	RCRO7G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R11	RCR07G823JR	CC, 82K ohm, 1/4W, 5%	Allen Bradley	5-10823
R12	RCR07G470JR	CC, 47 ohm, 1/4W, 5%	Allen Bradley	5-10470
R13	RCR07G474JR	CC, 470K ohm, 1/4W, 5%	Allen Bradley	5-10474
R14	RCR07G224JR	CC, 220K ohm, 1/4W, 5%	Allen Bradley	5-10224
R15	RCR07G223JR	22K ohm, 1/4W, 5%	Allen Bradley	5-10223
R16	RCR07G302JR	CC, 3K ohm, 1/4W, 5%	Allen Bradley	5-10302
R17	RCR07G302JR	CC, 3K ohm, 1/4W, 5%	Allen Bradley	5-10302

Table 2. Parts List (Power Supply Board Sub-Assy 51105001) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
R18	RCR32G100JR	CC, 10 ohm, 1W, 5%	Allen Bradley	5-30100
R19	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R20	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R21	RCR20G511JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R22	RCR20G511JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R23	RCR32G511JR	CC, 5.1 ohm, 1W, 5%	Allen Bradley	5-31510
R24	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R25	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R26	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R27	RN55D1243F	MG, 124K ohm, 1/8W, 1%	Allen Bradley	5-51403
R28	RCR07G392JR	CC, 3.9K ohm, 1/4W, 5%	Allen Bradley	5-10392
R29	RCR07G395JR	CC, 3.9M ohm, 1/4W, 5%	Allen Bradley	5-10395
R30	RN55D90902F	MF, 90.9K ohm, 1/8W, 1%	Allen Bradley	5-51403
R31	RN55D90902F	MF, 90.9K ohm, 1/8W, 1%	Allen Bradley	5-51403
R32	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10473
R33	RN55D1243F	MF, 124K ohm, 1/8W, 1%	Allen Bradley	5-51403
R34	RCR07G395JR	CC, 3.9M ohm, 1/4W, 5%	Allen Bradley	5-10395
R35	RCR07G392JR	CC, 3.9K ohm, 1/4W, 5%	Allen Bradley	5-10392
R36	RCR07G683JR	CC, 68K ohm, 1/4W, 5%	Allen Bradley	5-10683
R37	RCR07G472JR	CC, 4.7K ohm, 1/4W, 5%	Allen Bradley	5-10472
R38	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R39	RCR07G392JR	CC, 3.9K ohm, 1/4W, 5%	Allen Bradley	5-10392
R40	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R41	RCR07G473JR	CC, 47K ohm, 1/4W, 5%	Allen Bradley	5-10472
R42	RCR07G683JR	CC, 68K ohm, 1/4W, 5%	Allen Bradley	5-10683
R43	RCR07G395JR	CC, 3.9M ohm, 1/4W, 5%	Allen Bradley	5-10395
R44	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R45	RCR07G683JR	CC, 68K ohm, 1/4W, 5%	Allen Bradley	5-10683
R46	RCR07G395JR	CC, 3.9M ohm, 1/4W, 5%	Allen Bradley	5-10395
R47	RCR07G392JR	CC, 3.9K ohm, 1/4W, 5%	Allen Bradley	5-10392
R48	RCR07G682JR	CC, 68K ohm, 1/4W, 5%	Allen Bradley	5-10682
R49	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R50	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R51	RCR07G823JR	CC, 82K ohm, 1/4W, 5%	Allen Bradley	5-10823
R52	RCR07G470JR	CC, 47 ohm, 1/4W, 5%	Allen Bradley	5-10470
R53	RCR07G470JR	CC, 47 ohm, 1/4W, 5%	Allen Bradley	5-10470
R54	RCR20G105JR	CC, 1M ohm, 1/2W, 5%	Allen Bradley	5-20105
R55	RCR20G223JR	CC, 22 K ohm, 1/2W, 5%	Allen Bradley	5-20223

TRANSISTORS

Q1	2N3906	PNP	Fairchild	3-23906
Q2	2N3904	NPN	Fairchild	3-23904
Q3	2N3906	PNP	Fairchild	3-23906
Q4	2N3904	NPN	Fairchild	3-23904
Q5	2N3906	PNP	Fairchild	3-23906
Q6	2N3906	PNP	Fairchild	3-23906
Q7	2N2907A	PNP	National	3-22907
Q8	2N2222A	NPN	National	3-22222

TRANSFORMER

T1	ST2-48	PC Mount, 50V Supply	Signal	7-61037
M1	T-00-9	Elapsed Time Meter	Frederics	4-20500

Table 3. Parts List (Switch Board Sub-Assy 51105002)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51103002	ETCHED CIRCUIT BOARD		51103002
CAPACITORS				
C1	CACO3Z5U104 ZO5OALTR	MONO, .1uf, 50V	Corning	6-36104
C2	ULBIE222M	ELECT, 2200uf, 25V	Nichicon	6-87002
C3	CACO3Z5U104 ZO5OALTR	MONO, .1uf, 50V	Corning	6-36104
C4	ULBIE222M	ELECT, 2200uf, 25V	Nichicon	6-87002
C5	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C6	CM05GD101D03	DM, 100Pf, 500V	Corn'l Dubilier	6-19101
C7	CM05GD330D03	CM, 33Pf, 500V	Corn'l Dubilier	6-19330
C8	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C9	CM05GD050D03	DM, 5Pf, 500V	Corn'l Dubilier	6-19050
C10	A11A105J	MM, 1uf, 50V	Bishop	6-46105
C11	A11A254J	MM, .25uf, 50V	Bishop	6-46254
C12	A11A105J	MM, .1uf, 50V	Bishop	6-46105
C13	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C14	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C15	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C16	2DDH611J103XAJ	CD, .01uf, 150V	Centralab	6-27103
CONNECTORS				
J3	3000-006-2103	PC CONN - 6 PIN	Methode	2-24061
J4	3000-006-2103	PC CONN - 6 PIN	Methode	2-24061
P2	1-640454-5	HEADER - 15 PIN	AMP	2-24030
DIODES				
CR1	FD300	Small Signal Diode	Fairchild	3-10300
CR2	FD300	Small Signal Diode	Fairchild	3-10300
CR3	IN914	Small Signal Diode	ITT	3-10914
CR4	IN914	Small Signal Diode	ITT	3-10914
CR5	IN914	Small Signal Diode	ITT	3-10914
CR6	IN914	Small Signal Diode	ITT	3-10914
CR7	IN914	Small Signal Diode	ITT	3-10914
INTEGRATED CIRCUITS				
U1	TI081ACP	FET OP-AMP	Texas Instrum.	3-0081
U2	TI081ACP	FET OP-AMP	Texas Instrum.	3-0081
U3	LM308AN	Low-Offset OP-AMP	National	3-30308
RESISTORS				
R1	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R2	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R3	RN55D9092D	MF, 90.9K ohm, 1/8W, .5%	Allen Bradley	5-56390
R4	RN55D9091D	MF, 9.09K ohm, 1/8W, .5%	Allen Bradley	5-56295
R5	RN55D9090D	MF, 909 ohm, 1/8W, .5%	Allen Bradley	5-56189
R6	RN55D90R9D	MF, 90.0 ohm, 1/8W, .5%	Allen Bradley	5-56092
R7	RN55D10R2D	MF, 10.2 ohm, 1/8W, .5%	Allen Bradley	5-56001
R8	RCR07G433JR	CC, 4.3K ohm, 1/4W, 5%	Allen Bradley	5-10433
R9	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R10	RN55D9092D	MF, 9.09K ohm, 1/8W, .5%	Allen Bradley	5-56295
R11	RCR07G430JR	CC, 430 ohm, 1/4W, 5%	Allen Bradley	5-10430

Table 3. Parts List (Switch Board Sub-Assy 51105002) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
R12	RCR07G105JR	CC, 1M ohm, 1/4W, 5%	Allen Bradley	5-10105
R13	RN55D1020F	MF, 102 ohm, 1/8W, 1%	Allen Bradley	5-51097
R14	RN55D9090D	MF, 909 ohm, 1/8W, .5%	Allen Bradley	5-56189
R15	RN55D1000F	MF, 100 ohm, 1/8W, 1%	Allen Bradley	5-51096
R16	RN55D10R0F	MF, 10.0 ohm, 1/8W, 1%	Allen Bradley	5-50000
R17	RW69VIRO	WW, 1.00 ohm, 2.5W, 1%	Dale	5-60358
R18	RN55D1003F	MF, 100K ohm, 1/8W, 1%	Allen Bradley	5-51394
R19	RN55D1001F	MF, 1.00K ohm, 1/8W, 1%	Allen Bradley	5-51193
R20	RCR07G100JR	CC, 10 ohm, 1/4W, 5%	Allen Bradley	5-10100
R21	RN55D1000F	MF, 100 ohm, 1/8W, 1%	Allen Bradley	5-51096
R22	RN55D1002F	MF, 10.0K ohm, 1/8W, 1%	Allen Bradley	5-51299
R23	RN55D1002F	MF, 10.0K ohm, 1/8W, 1%	Allen Bradley	5-51299
R24	RCR07G822JR	CC, 8.2K ohm, 1/4W, 5%	Allen Bradley	5-10822
R25	RN55D1003F	MF, 100K ohm, 1/8W, 1%	Allen Bradley	5-51394
R26	RN55D4992F	MF, 49.9K ohm, 1/8W, 1%	Allen Bradley	5-51366
R27	RN55D1583F	MF, 158K ohm, 1/8W, 1%	Allen Bradley	5-51413
R28	RCR07G303JR	CC, 30K ohm, 1/4W, 5%	Allen Bradley	5-10303
R29	RCR07G10JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R30	RCR07G106JR	CC, 10M ohm, 1/4W, 5%	Allen Bradley	5-10106
R31	RN55D4993F	MF, 499K ohm, 1/8W, 1%	Allen Bradley	5-51461
R32	RN55D4992F	MF, 49.9K ohm, 1/8W, 1%	Allen Bradley	5-51366
R33	RN55D4990F	MF, 499 ohm, 1/8W, 1%	Allen Bradley	5-51163
R34	RN55D4993F	MF, 499K ohm, 1/8W, 1%	Allen Bradley	5-51461
R35	RN55D4992F	MF, 49.9K ohm, 1/8W, 1%	Allen Bradley	5-51366
R36	RN55D4990F	MF, 499 ohm, 1/8W, 1%	Allen Bradley	5-51163
R37	RCR07G106JR	CC, 10M ohm, 1/4W, 5%	Allen Bradley	5-10106
R38	RN55D1021D	MF, 1.02K ohm, 1/8W, .5%	Allen Bradley	5-51194
SWITCHES				
S1	51102017	7 DECK PC MOUNT	V-D	51102017
S2	51102018	2-STATION P.B.	V-D	51102018
TRANSISTORS				
Q1	2N2907	PNP	National	3-22907
Q2	2N2222	NPN	National	3-22222
Q3	F2701	FET, N-CH	Solitron	3-22701
Q4	2N3904	PNP	Fairchild	3-23906
Q5	2N3904	PNP	Fairchild	3-23906
Q6	2N3906	NPN	Fairchild	3-23904
Q7	2N3904	NPN	Fairchild	3-23904
HARDWARE				
QTY 2	51102013	Knob, Push Button	V-D	51102013

Table 4. Parts List (Panel Board Sub-Assy 51105003)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51103003	PANEL BOARD		51103003
CAPACITORS				
C1	A11A105J	MM, 1uf, 50V	Bishop	6-46105
C2	CAC03Z5U104Z050ALTR	MONO, .1uf, 50V	Corning	6-36104
C3	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C4	503D107F016NB	ELECT, 100uf, 16V	Sprague	6-87107
C5	CAC03Z5U104Z050ALTR	MONO, .1ug, 50V	Corning	6-36104
C6	2DM15-681J	DM, 680Pf, 500V	Cornel Dublair	6-19681
C7	A32A223J	MM, .022uf	Bishop	6-46223
C8	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C9	2DDH61J103XAJ	CD, .01uf, 150V	Centralab	6-27103
C10	513D156M063AA4	ELECT, 15uf	Sprague	6-87156
C11	A11A105J	MM, 1uf, 50V	Bishop	6-46105
C12	A11A224J	MM, .22uf, 50V	Bishop	6-46224
C13	A11A473J	MM, .047uf, 50V	Bishop	6-46473
C14	XA2A103J	MM, .01uf, 50V	IMB	6-46103
C15	A11A104J	MM, .1uf, 50V	Bishop	6-46104
C16	DM15-101J	DM, 100PF, 500V	Cornel Dublair	6-19101
C17	503D107F016NB	ELECT, 100uf, 16V	Sprague	6-87107
C18	CAC03Z5U104Z050ALTR	MONO, .1uf, 50V	Corning	6-36104
C19	A32A223J	MM, .022uf, 400V	Bishop	6-46223
C20	503D107F016NB	ELECT, 100uf, 16V	Sprague	6-87107
C21	CAC03Z5U104Z050ALTR	MONO, .1uf, 50V	Corning	6-36104
C22	CAC03Z5U104Z050ALTR	MONO, .1uf, 50V	Corning	6-36104
COIL				
L1-L6	FB-43-101	Ferrite Bead	Amidon	5-90001
CONNECTORS				
P1	2-640454-0	Header, 20 Pin	AMP	2-24055
P2	1-640-454-5	Header, 15 Pin	AMP	2-24030
P3	3100-1-206-01	Header, 6 Pin	Methode	2-24062
P4	3100-1-206-01	Header, 6 Pin	Methode	2-24062
J1	3760-4	Jack, Banana, Yellow	Pomona	2-24063
J7	3760-4	Jack, Banana, Yellow	Pomona	2-24063
J8	3760-5	Jack, Banana, Green	Pomona	2-24064
J13	3760-5	Jack, Banana, Green	Pomona	2-24064
J3	3760-6	Jack, Banana, Blue	Pomona	2-24065
J9	3760-6	Jack, Banana, Blue	Pomona	2-24065
J2	640441	Jack, 5-Pin	AMP	2-24043
DIODES				
CR1	IN4576	Diode, Ziener 6.4V	Motorola	3-14576
CR2	IN914	Diode, Signal	ITT	3-10914
CR3	IN914	Diode, Signal	ITT	3-10914
CR4	IN914	Diode, Signal	ITT	3-10914
CR5	IN914	Diode, Signal	ITT	3-10914
CR6	IN914	Diode, Signal	ITT	3-10914
CR7	IN914	Diode, Signal	ITT	3-10914
CR8	IN914	Diode, Signal	ITT	3-10914

Table 4. Parts List (Panel Board Sub-Assy 51105003) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANU- FACTURER	VU-DATA PART NO.
CR9	IN914	Diode, Signal	ITT	3-10914
CR10	IN914	Diode, Signal	ITT	3-10914
CR11	IN914	Diode, Signal	ITT	3-10914
CR12	IN914	Diode, Signal	ITT	3-10914
CR13	IN914	Diode, Signal	ITT	3-10914
CR14	IN914	Diode, Signal	ITT	3-10914
CR15	IN914	Diode, Signal	ITT	3-10914
CR16	IN914	Diode, Signal	ITT	3-10914
CR17	IN914	Diode, Signal	ITT	3-10914
CR18	IN914	Diode, Signal	ITT	3-10914
CR19	IN914	Diode, Signal	ITT	3-10914
CR20	IN914	Diode, Signal	ITT	3-10914
CR21	IN914	Diode, Signal	ITT	3-10914
CR22	IN914	Diode, Signal	ITT	3-10914
CR23	IN914	Diode, Signal	ITT	3-10914
CR24	IN914	Diode, Signal	ITT	3-10914
CR25	IN914	Diode, Signal	ITT	3-10914
CR26	IN914	Diode, Signal	ITT	3-10914
CR27	IN914	Diode, Signal	ITT	3-10914
CR28	IN914	Diode, Signal	ITT	3-10914
CR29	IN914	Diode, Signal	ITT	3-10914
CR30	IN914	Diode, Signal	ITT	3-10914
CR31	IN914	Diode, Signal	ITT	3-10914
CR32	IN914	Diode, Signal	ITT	3-10914
CR33	IN914	Diode, Signal	ITT	3-10914
CR34	IN914	Diode, Signal	ITT	3-10914
CR35	IN914	Diode, Signal	ITT	3-10914
CR36	IN914	Diode, Signal	ITT	3-10914
CR37	IN914	Diode, Signal	ITT	3-10914
CR38	IN914	Diode, Signal	ITT	3-10914
CR39	IN914	Diode, Signal	ITT	3-10914
CR40	IN914	Diode, Signal	ITT	3-10914
CR41	IN914	Diode, Signal	ITT	3-10914
CR42	IN914	Diode, Signal	ITT	3-10914
CR43	IN914	Diode, Signal	ITT	3-10914
CR44	IN914	Diode, Signal	ITT	3-10914
CR45	IN914	Diode, Signal	ITT	3-10914
CR46	IN914	Diode, Signal	ITT	3-10914
CR47	IN914	Diode, Signal	ITT	3-10914
CR48	IN914	Diode, Signal	ITT	3-10914
CR49	IN914	Diode, Signal	ITT	3-10914
CR50	IN914	Diode, Signal	ITT	3-10914
CR51	IN914	Diode, Signal	ITT	3-10914
CR52	IN914	Diode, Signal	ITT	3-10914
CR53	IN914	Diode, Signal	ITT	3-10914
CR54	IN914	Diode, Signal	ITT	3-10914
CR55	IN914	Diode, Signal	ITT	3-10914
CR56	IN914	Diode, Signal	ITT	3-10914
CR57	IN914	Diode, Signal	ITT	3-10914
CR58	IN914	Diode, Signal	ITT	3-10914
CR59	IN914	Diode, Signal	ITT	3-10914
CR60	IN914	Diode, Signal	ITT	3-10914
CR61	IN914	Diode, Signal	ITT	3-10914
CR62	IN914	Diode, Signal	ITT	3-10914

Table 4. Parts List (Panel Board Sub-Assy 51105003) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
CR63	IN914	Diode, Signal	ITT	3-10914
CR64	IN914	Diode, Signal	ITT	3-10914
CR65	IN914	Diode, Signal	ITT	3-10914
CR66	IN914	Diode, Signal	ITT	3-10914
CR67	IN914	Diode, Signal	ITT	3-10914
CR68	IN914	Diode, Signal	ITT	3-10914
CR69	IN914	Diode, Signal	ITT	3-10914
CR70	IN914	Diode, Signal	ITT	3-10914
CR71	IN914	Diode, Signal	ITT	3-10914
CR72	IN914	Diode, Signal	ITT	3-10914
CR73	IN914	Diode, Signal	ITT	3-10914
INTEGRATED CIRCUITS				
U1	ICL7107CPL	DMM/LED Driver	Intersil	3-37107
U2	CA555CE	Timer	RCA	3-30555
U3	MC14011BCP	QUAD 2-INPUT NAND	Motorola	3-34011
U4	UA339DC	QUAD COMPARITOR	Motorola	3-30339
U5	TL081ACP	FET INPUT OP AMP	Texas Instr.	3-30081
LIGHTS				
DS1	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS2	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS3	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS4	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS5	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS6	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS7	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS8	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS9	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS10	HLMP-2300	LED LIGHT BAR-RED	H.P.	3-12300
DS11	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS12	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS13	5082-7750	7-Segment LED-RED	H.P.	3-17750
DS14	5331H1	RED LED w/base	Ind. Dev., Inc.	3-19102
DS15	5331H1	RED LED w/base	Ind. Dev., Inc.	3-19102
DS16	5331H1	RED LED w/base	Ind. Dev., Inc.	3-19102
CR17	5331H1	RED LED w/base	Ind. Dev., Inc.	3-19102
RESISTORS				
R1	RCR07G103JR	CC, 10K ohm, 1/4W, 5%	Allen Bradley	5-10103
R2	RCR07G822JR	CC, 8.2K ohm, 1/4W, 5%	Allen Bradley	5-10811
R3	RCR07G680JR	CC, 680 ohm, 1/4W, 5%	Allen Bradley	5-10681
R4	RCR07G150JR	CC, 150 ohm, 1/4W, 5%	Allen Bradley	5-10151
R5	RCR07G150JR	CC, 150 ohm, 1/4W, 5%	Allen Bradley	5-10151
R6	RCR07G333JR	CC, 33K ohm, 1/4W, 5%	Allen Bradley	5-10333
R7	RCR07G334JR	CC, 330K ohm, 1/4W, 5%	Allen Bradley	5-10334
R8	RCR07G333JR	CC, 33K ohm, 1/4W, 5%	Allen Bradley	5-10333
R9	RCR07G562JR	CC, 5.6K ohm, 1/4W, 5%	Allen Bradley	5-10562
R10	RCR07G333JR	CC, 33K ohm, 1/4W, 5%	Allen Bradley	5-10333
R11	RN55D2102F	MF, 21.0K ohm, 1/8W, 1%	Allen Bradley	5-51330
R12	RCR07G470JR	EE, 47 ohm, 1/4W, 5%	Allen Bradley	5-10470
R13	RN55D4320F	MF, 432 ohm, 1/8W, 1%	Allen Bradley	5-51157
R14	RN55D1211F	MF, 1.21K ohm, 1/8W, 1%	Allen Bradley	5-51201
R15	RN55D3013F	MF, 301K ohm, 1/8W, 1%	Allen Bradley	5-51440

Table 4. Parts List (Panel Board Sub-Assy 51105003) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
R16	RN5D1002F	MF, .10.0K ohm, 1/8W, 1%	Allen Bradley	5-51299
R17	RN55D1002F	MF, 10.0K ohm, 1/8W, 1%	Allen Bradley	5-51299
R18	RN55D49R9F	MF, 49.9 ohm, 1/8W, 1%	Allen Bradley	5-51067
R19	RCR07G474JR	CC, 470K ohm, 1/4W, 5%	Allen Bradley	5-10474
R20	RN55D8252F	MF, 82.5K ohm, 1/8W, 1%	Allen Bradley	5-51386
R21	RN55D3572F	MF, 35.7K ohm, 1/8W, 1%	Allen Bradley	5-51352
R22	RCR076106JR	CC, 10M ohm, 1/4W, 5%	Allen Bradley	5-10106
R23	RN55D4753F	MF, 475K ohm, 1/8W, 1%	Allen Bradley	5-51459
R24	RN55D4122F	MF, 41.2K ohm, 1/8W, 1%	Allen Bradley	5-51358
R25	RN55D6192F	MF, 61.9K ohm, 1/8W, 1%	Allen Bradley	5-51374
R26	RCR07G474JR	CC, 470K ohm, 1/4W, 5%	Allen Bradley	5-10474
R27	RN55D1501F	MF, 1.50K ohm. 1/8W, 1%	Allen Bradley	5-51210
R28	3386S-1-102	POT, 1K ohm	Bourns, Inc	5-73102
R29	RN55D2491F	MF, 2.49K ohm, 1/8W, 1%	Allen Bradley	5-51231
R30	RN55D1003F	MF, 100K ohm, 1/8W, 1%	Allen Bradley	5-51394
R31	RN55D4642F	MF, 4.64K ohm, 1/8W, 1%	Allen Bradley	5-51267
R32	RCR07G472JR	CC, 4.7K ohm, 1/4W, 5%	Allen Bradley	5-10472
R33	RCR07G472JR	CC, 4.7K ohm, 1/4W, 5%	Allen Bradley	5-10472
R34	RCR07G105JR	CC, 1M ohm, 1/4W, 5%	Allen Bradley	5-10105
R35	RN55D4642F	MF, 4.64K ohm, 1/8W, 1%	Allen Bradley	5-51267
R36	RCR07G105JR	CC, 1M ohm, 1/4W, 5%	Allen Bradley	5-10105
R37	RN55D3010F	MF, 301 ohm, 1/8W, 1%	Allen Bradley	5-51142
R38	RN55D3010F	MF, 301 ohm, 1/8W, 1%	Allen Bradley	5-51142
R39	RCR07G105JR	CC, 1M ohm, 1/4W, 5%	Allen Bradley	5-10105
R40	RCR07G105JR	CC, 1M ohm, 1/4W, 5%	Allen Bradley	5-10105
R41	RN55D1020F	MF, 102 ohm, 1/8W, 1%	Allen Bradley	5-51097
R42	RN55D1020F	MF, 102 ohm, 1/8W, 1%	Allen Bradley	5-51097
R43	RCR07G822JR	CC, 8.2K ohm, 1/4W, 5%	Allen Bradley	5-10822
R44	RCR07G470JR	CC, 470 ohm, 1/4W, 5%	Allen Bradley	5-10470
R45	RCR07G822JR	CC, 8.2K ohm, 1/4W, 5%	Allen Bradley	5-10822
R46	RCR07G470JR	CC, 470 ohm, 1/4W, 5%	Allen Bradley	5-10471
R47	RCR07G510JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R48	RCR07G510JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R49	RCR07G103JR	CC, 10K ohm, 1/4W, 5%	Allen Bradley	5-10103
R50	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R51	RCR07G103JR	CC, 10K ohm, 1/4W, 5%	Allen Bradley	5-10103
R52	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R53	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R54	RCR07G510JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R55	RCR07G510JR	CC, 510 ohm, 1/4W, 5%	Allen Bradley	5-10511
R56	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R57	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R58	RN60D1004F	MF, 1M ohm, 1/4W, 1%	Allen Bradley	5-50490
R59	RCR42200JR	CC, 20 ohm, 2W, 5%	Allen Bradley	5-40200
R60	RCR42750JR	CC, 75 ohm, 2W, 5%	Allen Bradley	5-40750
R61	RCR42330JR	CC, 33 ohm, 2W, 5%	Allen Bradley	5-40330
R62	RCR42432JR	CC, 4.3K ohm, 2W, 5%	Allen Bradley	5-40432
R63	RCR07G680JR	CC, 680 ohm, 1/4W, 5%	Allen Bradley	5-10681
R64	RCR07G680JR	CC, 680 ohm, 1/4W, 5%	Allen Bradley	5-10681
R65	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R66	RCR07G433JR	CC, 43K ohm, 1/4W, 5%	Allen Bradley	5-10433
R67	RCR07G222JR	CC, 2.2K ohm, 1/4W, 5%	Allen Bradley	5-10222
R68	RCR07G750JR	CC, 750 ohm, 1/4W, 5%	Allen Bradley	5-10751
R69	RCR07G750JR	CC, 750 ohm, 1/4W, 5%	Allen Bradley	5-10751

Table 4. Parts List (Panel Board Sub-Assy 51105003) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
R70	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R71	RCR07G102JR	CC, 750 ohm, 1/4W, 5%	Allen Bradley	5-10750
R72	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R73	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R74	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R75	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R76	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R77	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R78	RCR07G222JR	CC, 2.2K ohm, 1/4W, 5%	Allen Bradley	5-10222
R79	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R80	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R81	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R82	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R83	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R84	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R85	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R86	RCR07G222JR	CC, 2.2K ohm, 1/4W, 5%	Allen Bradley	5-10222
R87	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R88	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R89	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R90	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R91	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R92	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R93	RCR07G102JR	CC, 1K ohm, 1/4W, 5%	Allen Bradley	5-10102
R94	RCR07G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R95	RCR08G104JR	CC, 100K ohm, 1/4W, 5%	Allen Bradley	5-10104
R96	RCR07G222JR	CC, 2.2K ohm, 1/4W, 5%	Allen Bradley	5-10222
R97	RCR07G222JR	CC, 2.2K ohm, 1/4W, 5%	Allen Bradley	5-10222
R98	RCR07G223JR	CC, 22K ohm, 1/4W, 5%	Allen Bradley	5-10223
R99	RCR07G223JR	CC, 22K ohm, 1/4W, 5%	Allen Bradley	5-10233
R100	70AIN100P102U	MOD POT, 1K ohm	Allen Bradley	5-79531
R101	70CIN100P102/504U	DUAL MOD POT, 1K ohm	Allen Bradley	5-79532
R102		Ref (R101), 500K ohm		
R103	70KIN100P102U	MOD POT, SWITCH-S4 1K ohm	Allen Bradley	5-79530

TRANSISTORS

Q1	2N5401	PNP,	Motorola	3-25401
Q2	2N5401	NPN,	Motorola	3-25401
Q3	2N5550	NPN,	Fairchild	3-25550
Q4	2N5550	NPN,	Fairchild	3-25550
Q5	2N3904	NPN,	Fairchild	3-23904
Q6	2N5550	NPN,	Fairchild	3-25550
Q7	2N5550	NPN,	Fairchild	3-25550
Q8	2N3906	PNP,	Fairchild	3-23906
Q9	2N3906	PNP,	Fairchild	3-23906
Q10	2N3904	NPN,	Fairchild	3-23904
Q11	2N3904	NPN,	Fairchild	3-23904
Q12	2N3904	NPN,	Fairchild	3-23904
Q13	2N3904	NPN,	Fairchild	3-23904
Q14	2N3906	PNP,	Fairchild	3-23906
Q15	2N3906	PNP,	Fairchild	3-23906
Q16	2N3904	NPN,	Fairchild	3-23904
Q17	2N3904	NPN,	Fairchild	3-23904
Q18	2N3904	NPN,	Fairchild	3-23904

PARTS LIST

Table 4. Parts List (Panel Board Sub-Assy 51105003) (Continued)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
Q19	2N3904	NPN,	Fairchild	3-23904
Q20	2N3904	NPN,	Fairchild	3-23904
Q21	2N3904	NPN,	Fairchild	3-23904
Q22	2N3904	NPN,	Fairchild	3-23904
Q23	2N3904	NPN,	Fairchild	3-23904
Q24	2N3904	NPN,	Fairchild	3-23904
Q25	F2701	N-CH FET	Solitron	3-22701
Q26	MPSA18	NPN,	Motorola	3-20018
Q27	MPSA18	NPN,	Motorola	3-20018
QTY 8	22FT-632	#6 Locknut		8-90003
QTY 4	79NM-40	#4 Locknut		8-90034
QTY 4	MS51957-20	4-40 5/8" Pan HD, SS		8-10020
QTY 8	MS51957-33	6-32 7/8" Pan HD		8-10033
QTY 8	#9207	Alum, Stdoff, #6 CL, .187 x 1/4 Dia	H.S. Smith	4-20501
QTY 8	#2670	Nylon Washer	H.H. Smith	8-60015
S1	7201-J1-V3-Q-E	Switch, PC Mount, Rocker	C.K.	2-10074
S2	5110 2019	Switch, 3 Deck, 10 Pos	V-D	5110 2019
S3	7201-J1-V3-Q-E	Switch, PC Mount, Rocker	C.K.	2-10074
S4		Switch, Mod Pot		Part of R103
QUANTITY		SOCKETS		
2	203-4050-00-1105	TO5	Textool	2-60021
2	203-2492-00-1125	TO3	Textool	2-60022
2	203-2702-00-1125	TO66	Textool	2-60023
7	DIL-B14P108	14 PIN	Burndy	2-60013
1	DIL-B40P108	40 PIN	Burndy	2-60017
1	CDH-4000-16	16 PIN	Burndy	2-60009
1	DIL-B8P108	8 PIN	Burndy	2-60024
		HARDWARE		
QTY 2	MS51957-14	4-40 5/16" Pan Head		8-10014
QTY 1	51102010	Fuseholder Bracket	V-D	51102010
QTY 2	MS35333-70	4-40 Int. Star Lk. Washer		8-40002
QTY 3	031.1673	Fuse Holder	PNL.COMP	2-40021
QTY 3	031.1666	Fuse Carrier 3AG	PNL.COMP	2-40022
QTY 3	905-023	1/2" Int. Lockwasher, Small O.D.	Littlefuse	8-90035
F1	313.250	Fuse 1/4A S.B.	Littlefuse	2-40004
F2	313.250	Fuse 1/4A S.B.	Littlefuse	2-40004
F3	313.250	Fuse 1/4A S.B.	Littlefuse	2-40004

Table 5. Parts List (Power Supply Assy 51105004)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51105001	Power Supply Board Sub-Assy		51105001
	51102008	Power Supply Bracket		51102008
T1	241-5-16	Transformer	Signal	7-61036
P1	EAC-301	Line Cord Socket	Switchcraft	2-24000
QTY 2	AD44ABS	Pop Rivet	USM	4-20344
QTY 2	MS15795-806	Backing Washer		8-50003
S1	7201J1ZQ	Power Switch DPDT	C.K.	2-10075
QTY 1	031.1673	Fuse Holder	Pnl. Comp.	2-40021
QTY 1	031.1666	Fuse Carryer 3AG	Pnl. Comp.	2-40022
QTY 1	1/2" Int. Star	Fuse Lock Washer		8-90035
F1	313.250	Fuse 1/4 A S.B.	Littlefuse	2-40004
QTY 1	79NM-40	#4 Nut-Locking		8-90034
QTY 4	MS51957-3	#2-56 1/4 Pan Head		8-10003
QTY2	MS51957-14	#4-40 5/16 Pan Head		8-10014
QTY 2	2630-N-12425-093	Nylon Shoulder Washer	Seastrom	8-60001
QTY 2	7403-09FR-51	Sil Pad	Burquist	4-20290
QTY 1	1410-4	#4 Ground Lug		4-20296
QTY 2	NAS671C8	#8-32 Nut		8-30007
QTY 2	MS35333-72	#8 Int. Star Lock Washer		8-40004

Table 6. Parts List (Chassis Assy 51105005)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51105004	Power Supply Assy		51105004
	51105003	Panel Board Assy		51105003
	51105002	Switch Board Assy		51105002
		15 Pin Cable Assy		4-20504
QTY 2	1-640441-5	Connector 15 Pin	Amp	2-24034
QTY 4"	112-2405-115	Ribbon Cable, 15 cond.	Spectrastrip	2-70021
		20 Pin Cable Assy		4-20505
QTY 2	2-640441-0	Connector 20 Pin	Amp	2-24056
QTY 8"	112-2405-120	Ribbon Cable, 20 cond.	Spectrastrip	2-70023
L1	25SP003	Speaker	Mouser	5-90103
J3	1300-102	2 Pin Jack	Methode	2-24033
QTY 2	1400-113	Pin- Female	Methode	2-24038
	51102001	Side Panel — Left		51102001
	51102002	Side Panel — Right		51102002
	51102003	Rear Support		51102003
	51102004	Front Support		51102004
	51102005	Top Support		51102005
	51102006	Pan Bd Bracket — Left		51002006
	51102007	Pan Bd Bracket — Right		51102007
	51102009	Middle Support		51102009
QTY 1	1410-4	#4 Ground Lug		4-20296
QTY 13	MS51957-14	#4-40 × 5/16 Pan Hd		8-10014
QTY 8	MS24693-3	#4-40 × 5/16 Flat Hd		8-30014
QTY 6	NS24693-27	#6-32 × 7/16 Flat Hd		8-20029
QTY 11	79NM-40	#4-40 Lock Nuts		8-90034

Table 7. Parts List (Final Assembly 51105006)

REFERENCE DESIGNATOR	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
	51105005	Chassis Assembly	V-D	51105005
	51102012	Rear Panel	V-D	51102012
	51102011	Front Panel	V-D	51102011
	51102015	Filter — Parameter	V-D	51102015
	51102014	Filter — Go/No-Go	V-D	51102014
	51102016	Serial Number Decal	V-D	51102016
	9352080	Calibration Tag	V-D	4-20312
QTY 1	7861-315-314	Handle, Plastic	Phil. Hndl Co.	1-10852
QTY 2	230-10AL8-32A	Handle, 4", Black	Promptus	4-10033
QTY 4	F6B	#6 Foot	Budwig	4-20177
QTY 2	PS-70BL-2 BLK	Knob, Large	Buckeye	4-10034
QTY 3	PS-50D-2 BLK (Short)	Knob, Small	Buckeye	4-10035
QTY 14	MS51957-14	4-40 × 5/16 Pan Head		8-10014
QTY 5	79NM-40	4-40 Lock Nut		8-90034
QTY 4	MS51957-28	6-32 × 3/8 Pan Head		8-10028
QTY 2	MS24693-26	6-32 × 3/8 Flat Head		8-20028
QTY 4	MS24693-46	8-32 × 1/4 Flat Head		8-20041

Table 8. Parts List (Miscellaneous 5110)

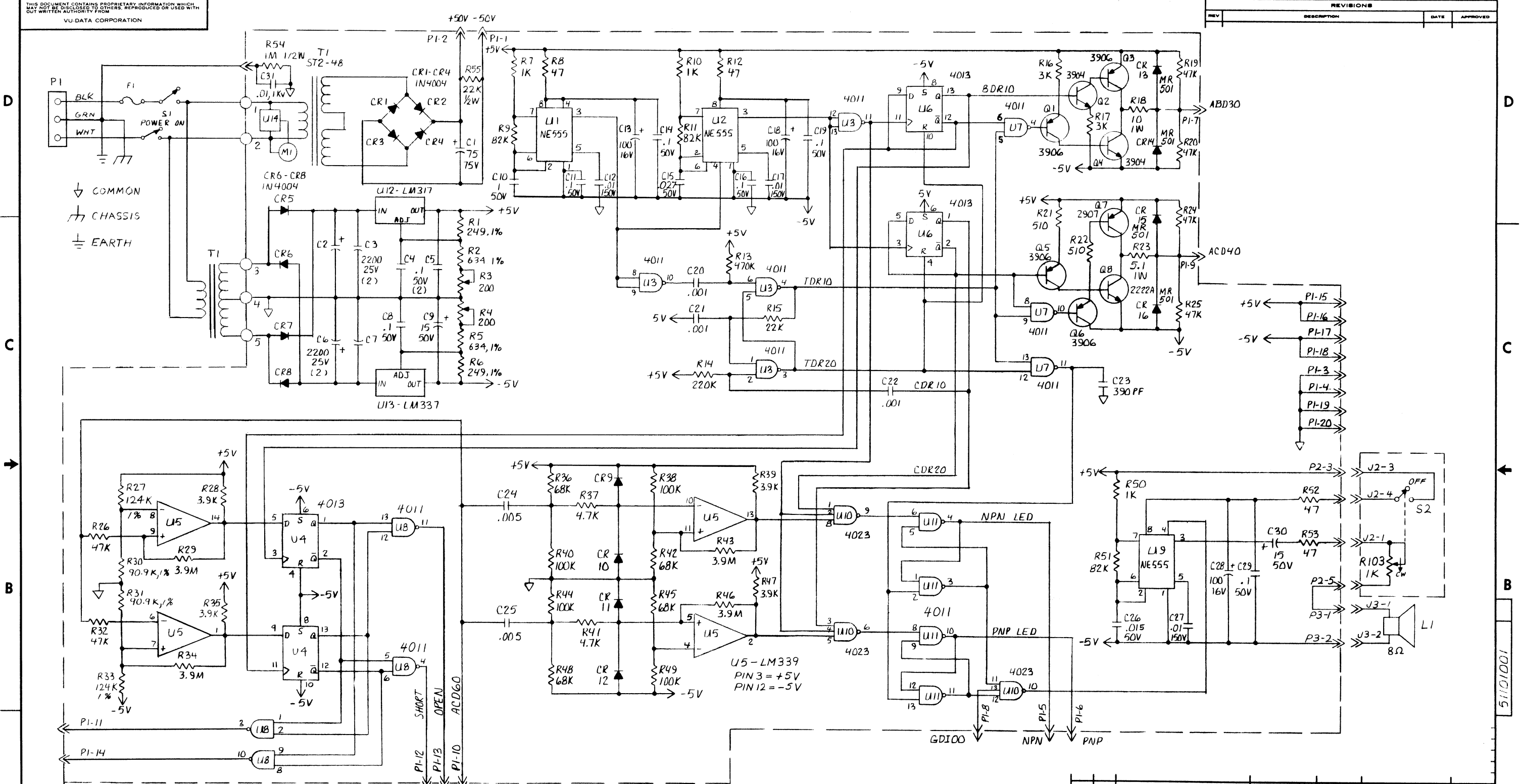
QUANTITY	MANUFACTURER PART NUMBER	DESCRIPTION	MANUFACTURER	VU-DATA PART NO.
1	Leader LP11-5'	Probe — 3 Prong with 3 Cond. Cable, 5' Long	Leader	4-20414
1	4-20415	Mini-Grabber Set	V-D	4-20415
1	203-4050-00-1105	Socket — TO5	Textool	2-60021
1	203-2492-00-1125	Socket — TO3	Textool	2-60022
1	203-2702-00-1125	Socket — TO66	Textool	2-60023
4	313.250	Fuse 1/4 A SB 3AG	Littlefuse	2-40004
1	51102020	Pouch/Case	V-D	51102020
1	4-20413	Manual	V-D	4-20413
1	SPH-386	Line Cord	Belden	2-70005

This manual contains the following drawings:

Title	Drawing Number
Schematic Power Supply	51101001
Schematic Switch Board	51101002
Schematic Panel Board—Parameter	51101003, sh 1
Schematic Panel Board—Go/No-Go Section	51101003, sh 2
Wiring Diagram Model 5110	51101008
Power Supply Sub-Assy	51105001
Switch Board Assy	51105002
Panel Board Assy	51105003
Outline Drawing Model 5110	51105007

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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED



6. R103, S4, & J2 MOUNTS ON PANEL BOARD
 5. L1 (SPEAKER) MOUNTED ON RIGHT SIDE PANEL
 4. U3, U4, U6, U7, U8, U10, & U11 SUPPLY PINS ARE:
 V_{DD} - PIN 14, & V_{SS} - PIN 7
 3. DIODES ARE INSI4
 2. CAPACITANCE IS IN MICROFARADS, 500V
 1. RESISTANCE IS IN OHMS, 1/4W, 5%, 1% IS 1/8W
- NOTES: UNLESS OTHERWISE SPECIFIED

ITEM NO.	QTY REQD	DESCRIPTION	SCHEM DES	VU-DATA PH	MFG. OR VENDOR PH	CODE OR SPEC NO.

LIST OF MATERIAL

UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES TOLERANCES ON:		CONTRACT NO.	
FRACTIONS	DECIMALS	DRAWN C. Pappat 84-2-1	
ANGLES		CHECKED J. G. Lee 7/7/85	
SURFACE FINISH		ENGINEER	
MATERIAL		APPROVED	
		APPROVED	
		APPROVED	
		CUSTOMER APPROVAL	
		RELEASE	

VU-DATA CORPORATION		SAN DIEGO, CALIFORNIA	
SCHEMATIC POWER SUPPLY			
SIZE	CODE IDENT NO.	DRAWING NO.	REV
D	34160	51101001	
SCALE	NONE		SHEET 1 OF 1

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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED

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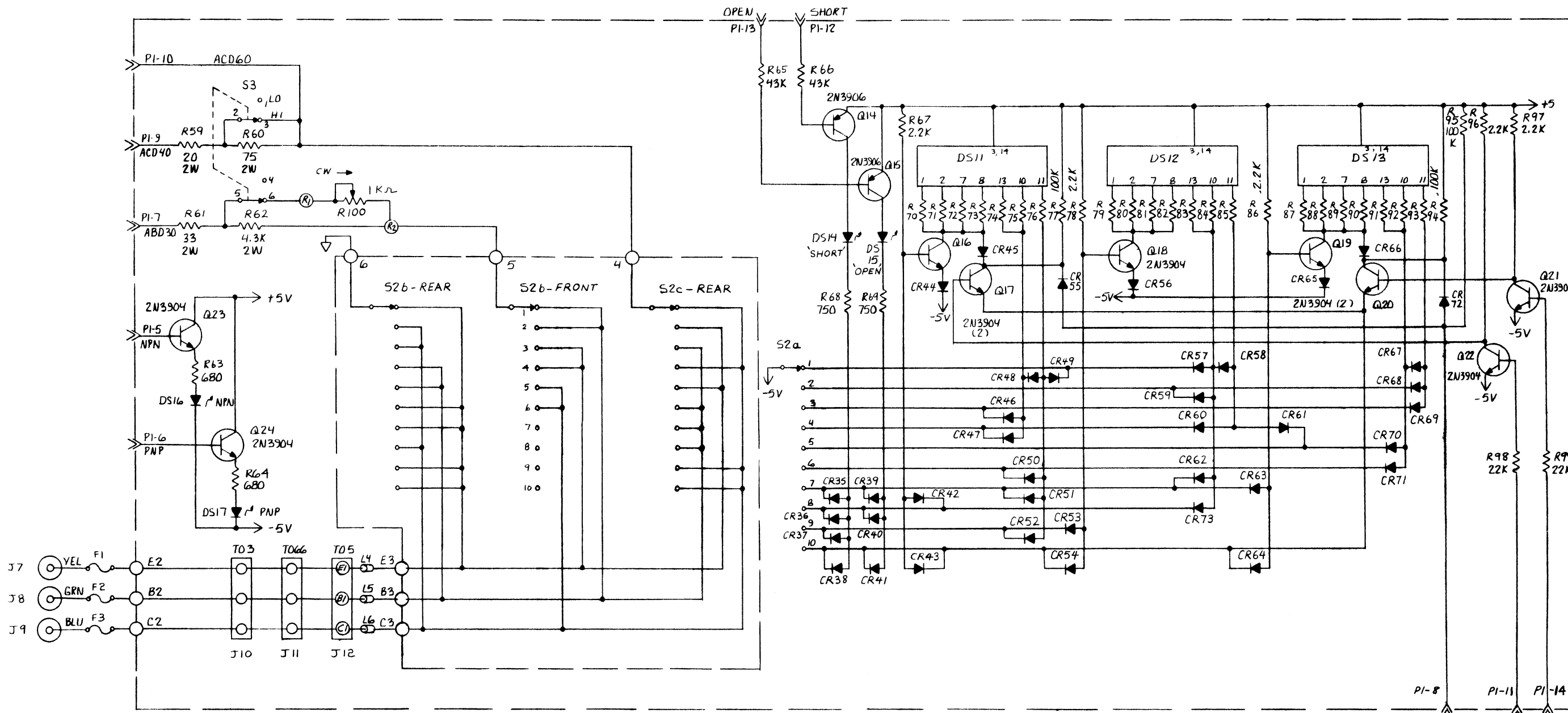
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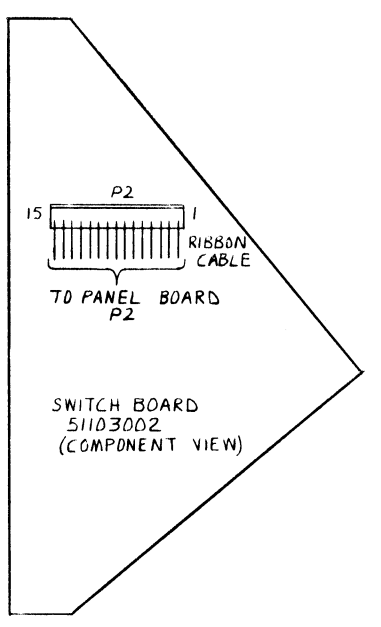
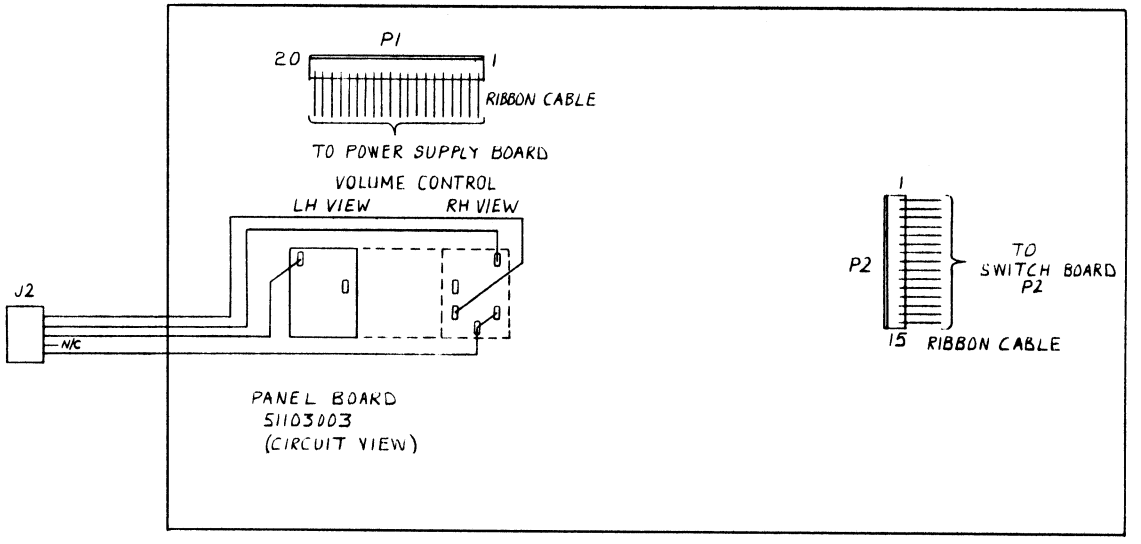
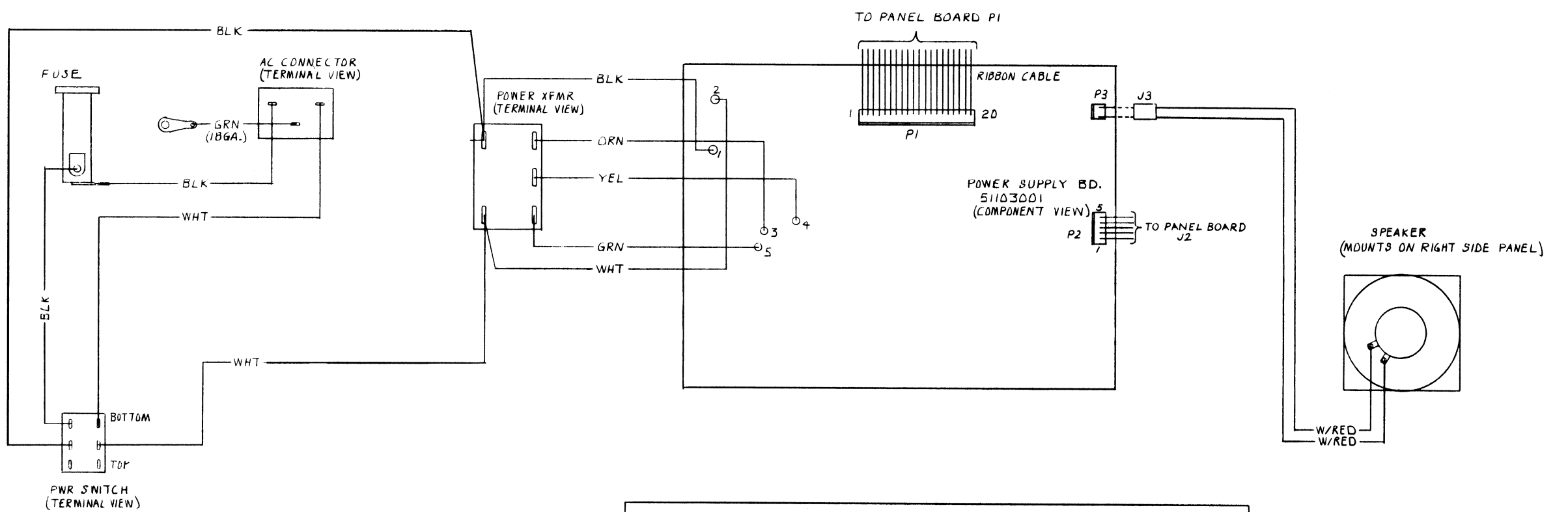
1. RESISTORS R70-76, R79-85, & R87-93 ARE 1K 5%
NOTES: UNLESS OTHERWISE SPECIFIED

ITEM NO.	QTY REQD	DESCRIPTION	SCHEM DES	VU-DATA PN	MIL OR VENDOR PN	CODE OR SPEC NO
LIST OF MATERIAL						
UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES			CONTRACT NO.			
TOLERANCES ON:			DRAWN <i>C. Probst 84-2-5</i>			
FRACTIONS 1/16			CHECKED <i>J. G. Lee 5/1/85</i>			
DECIMALS .X .020			ENGINEER			
ANGLES 1/16			APPROVED			
SURFACE FINISH .XXX 0.010			APPROVED			
MATERIAL			APPROVED			
FINISH			CUSTOMER APPROVAL			
PART NO.			SIZE		CODE IDENT NO.	
QTY REQD			D		34160	
NEXT ASSEMBLY			DRAWING NO.		51101003	
USED ON			SCALE		NONE	
APPLICATION			SHEET		2 OF 2	

51101003

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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED



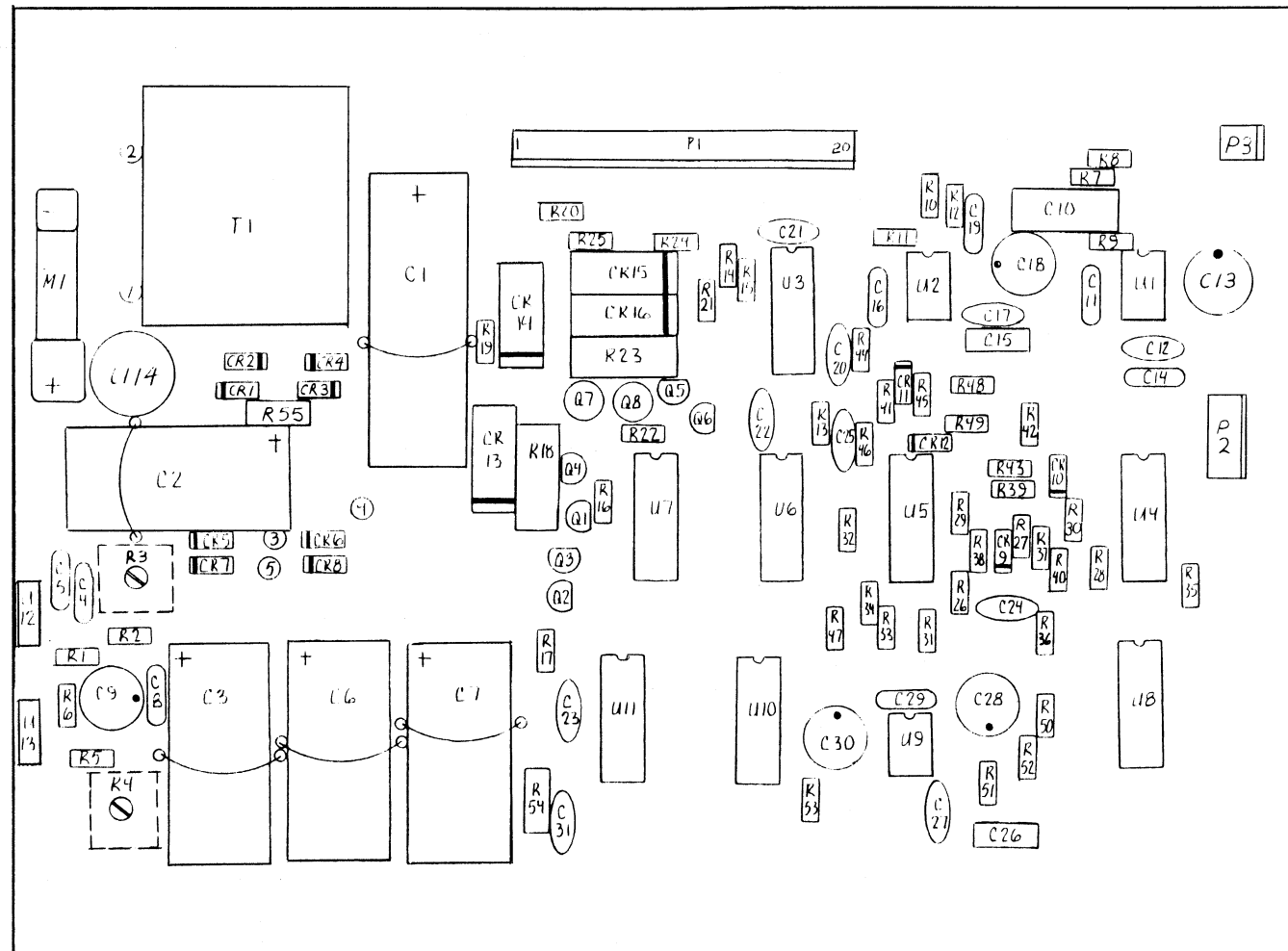
NOTES: UNLESS OTHERWISE SPECIFIED
 1- ALL WIRES ARE 24 GA.
 2- ALL NON-CIRCUIT BOARD COMPONENTS MOUNT TO POWER SUPPLY BRACKET

ITEM NO.	QTY	DESCRIPTION	SCHEM DES	VU-DATA PN	MIL OR VENDOR PN	CODE OR SPEC NO
LIST OF MATERIAL						
UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES			CONTRACT NO.			
TOLERANCES ON:			DRAWN <i>M S Miller</i> 5/10/84			
FRACTIONS & DECIMALS .X & .000			CHECKED <i>A G Lee</i> 5/1/85			
ANGLES & SURFACE FINISH ✓ .XXX & .010			ENGINEER			
MATERIAL			APPROVED			
FINISH			APPROVED			
APPLICATION			CUSTOMER APPROVAL			
RELEASE			SCALE NONE			

VU-DATA CORPORATION		SAN DIEGO, CALIFORNIA	
WIRING DIAGRAM MODEL 5110			
SIZE	CODE IDENT NO.	DRAWING NO.	REV
D	34160	51101008	
SHEET 1 OF 1			

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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED

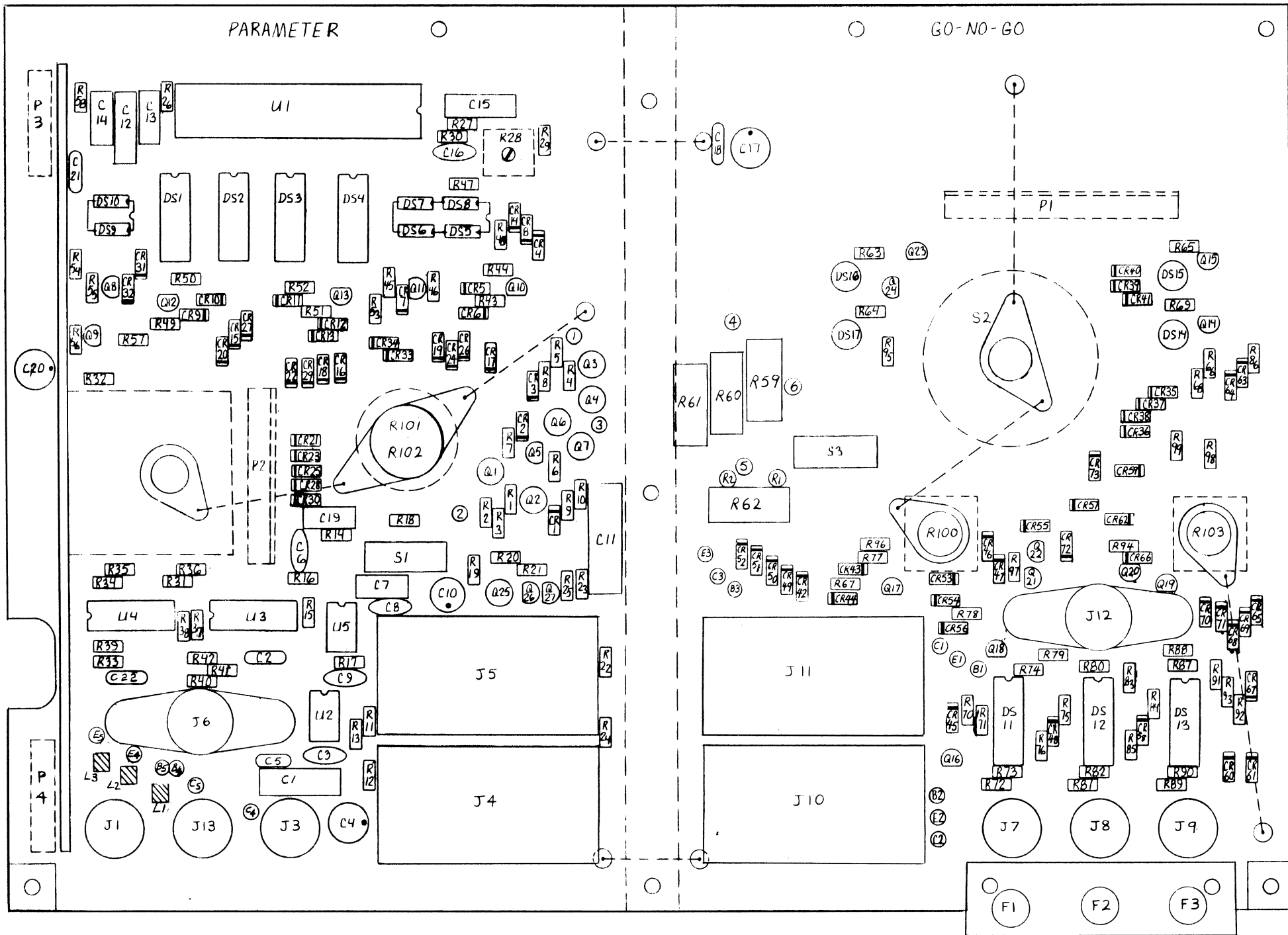


ITEM NO.	QTY REQD	DESCRIPTION	SCHEM DES	VU DATA PN	MIL OR VENDOR PN	CODE OR SPEC NO
LIST OF MATERIAL						
UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES			CONTRACT NO.			
TOLERANCES ON:			DRAWN <i>C. P. ... 4-3-84</i>			
FRACTIONS 1/16			CHECKED <i>RWA 3-10-84</i>			
DECIMALS .X 0.00			ENGINEER			
ANGLES 1/2			APPROVED			
SURFACE FINISH ✓			APPROVED			
MATERIAL			APPROVED			
FINISH			CUSTOMER APPROVAL			
PART NO. QTY REQD NEXT ASSEMBLY USED ON APPLICATION			SIZE		CODE IDENT NO.	DRAWING NO.
			D		34160	51105001
			SCALE 2/1		SHEET 1 OF 1	

VU-DATA CORPORATION
 SAN DIEGO, CALIFORNIA
POWER SUPPLY SUB-ASSY

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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED



ITEM NO.	QTY	DESCRIPTION	SCHEM DES	VU-DATA PN	ML OR VENDOR PN	CODE OR SPEC NO

UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES				CONTRACT NO.	
TOLERANCES ON:				DRAWN C.H. 3-10-89	
FRACTIONS & ANGLES		DECIMALS .X &.080		CHECKED RWA 3-15-89	
SURFACE FINISH		.XX &.010		ENGINEER	
MATERIAL				APPROVED	
FINISH				APPROVED	
APPLICATION				APPROVED	
PART NO.				CUSTOMER APPROVAL	
QTY REQ				SIZE	
NEXT ASSEMBLY				CODE IDENT NO	
USED ON				DRAWING NO.	
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				REV	
				SCALE 2:1	
				SHEET 1 OF 1	

VU-DATA CORPORATION
 SAN DIEGO, CALIFORNIA
ASSY PANEL BOARD

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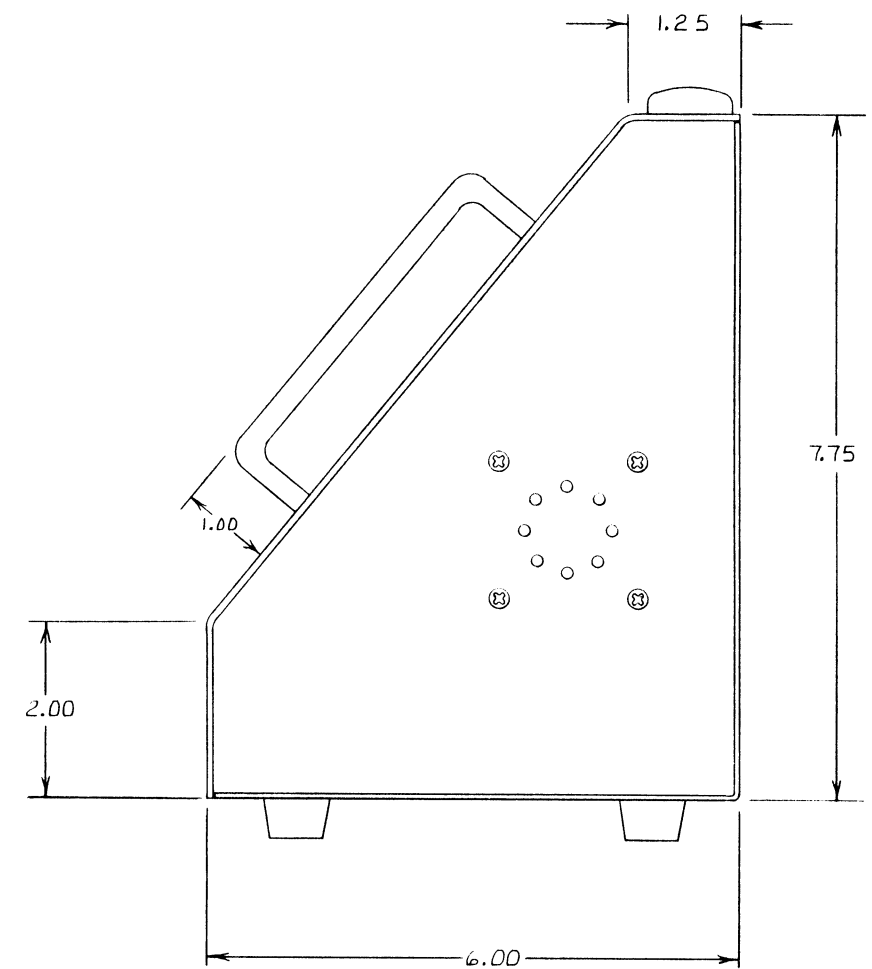
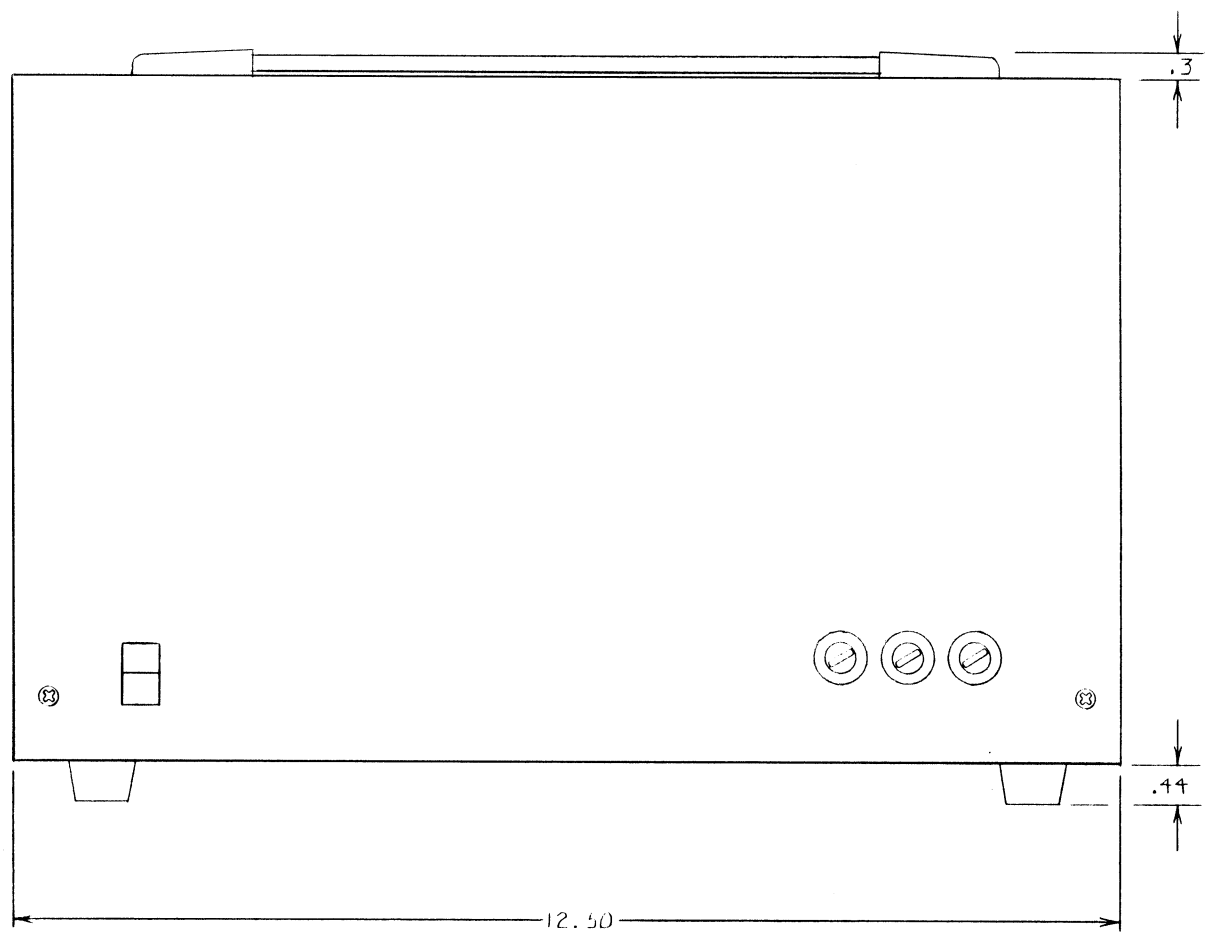
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REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
A	HANDLE 1.00 WAS 1.50	1/4/85	<i>R. W. A.</i>

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ITEM NO.	QTY REQD	DESCRIPTION	SCHEM DES	VU-DATA PN	MIL OR VENDOR PN	CODE OR SPEC NO
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UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES TOLERANCES ON: FRACTIONS ± .000 DECIMALS ± .000 ANGLES ± .XX ± .000 SURFACE FINISH ✓ .XXX ± .010 MATERIAL				CONTRACT NO.			
DRAWN <i>M. S. Pulla</i> 3/10/84				CHECKED		SAN DIEGO, CALIFORNIA	
ENGINEER <i>M. S. Pulla</i> 3/10/84				APPROVED		OUTLINE DRAWING	
APPROVED <i>R. W. A.</i> 3/19/85				CUSTOMER APPROVAL		MODEL 5110	
FINISH				RELEASE		SIZE D	CODE IDENT NO. 34160
APPLICATION				SCALE 1/1		DRAWING NO. 51105007	REV. A

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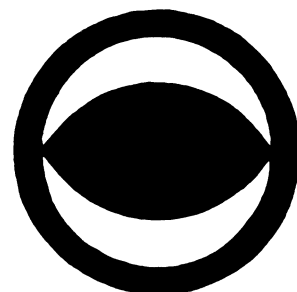
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SAN DIEGO, CA. 92121

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